

# 150V $V_{IN}$ and $V_{OUT}$ Synchronous 4-Switch Buck-Boost Controller + Switching Bias Supply

## FEATURES

- 4-Switch Current Mode Single Inductor Architecture Allows  $V_{IN}$  Above, Below or Equal to  $V_{OUT}$
- Wide  $V_{IN}$  Range: 4.5V to 150V
- Wide Output Voltage Range:  $1.2V \leq V_{OUT} \leq 150V$
- Synchronous Rectification: Up to 99% Efficiency
- $\pm 1\%$  1.2V Voltage Reference
- Input or Output Average Current Limit
- Integrated 12 $\mu$ A  $I_Q$ , 150V, 85mA, Switching Bias for Optimal Thermal Performance
- Programmable 6V to 10V  $DRV_{CC}$  Optimizes Efficiency
- No Top FET Refresh Noise in Boost or Buck Mode
- $V_{OUT}$  Disconnected from  $V_{IN}$  During Shutdown
- Phase-Lockable Fixed Frequency (50kHz to 600kHz)
- No Reverse Current During Start-Up
- 150V Rated RUN Pin with Accurate Turn-On Threshold
- Thermally Enhanced 48-Lead e-LQFP Package

## APPLICATIONS

- Industrial, Transportation, Medical, Military, Avionics

All registered trademarks and trademarks are the property of their respective owners.

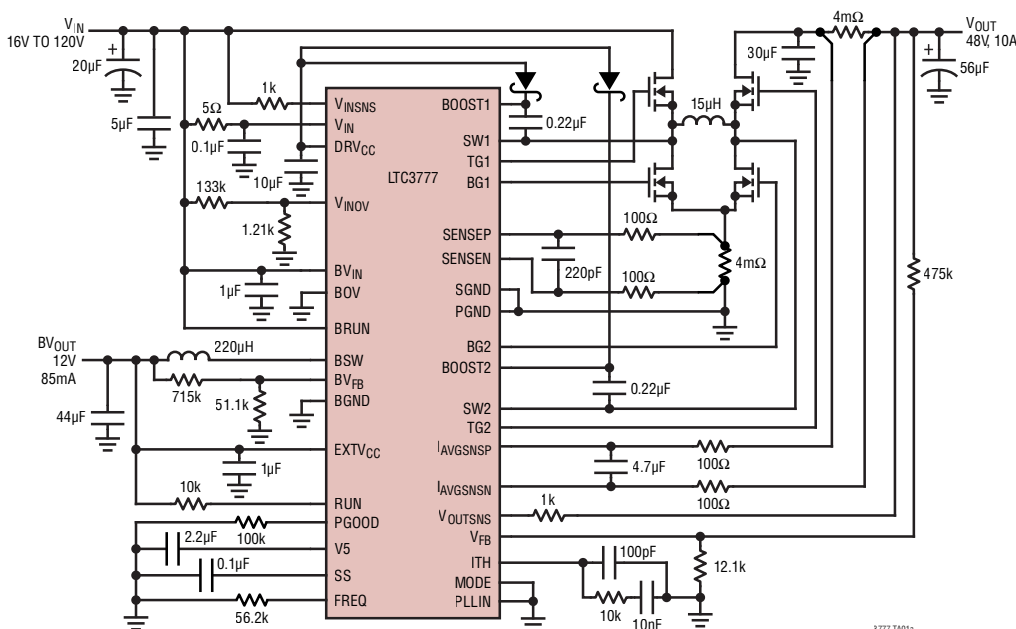
## DESCRIPTION

The LTC<sup>®</sup>3777 is a high performance buck-boost switching regulator controller that operates from input voltages above, below or equal to the output voltage. The constant frequency current mode architecture allows a phase-lockable frequency of up to 600kHz, while an input/output constant current loop provides support for battery charging. The 150V integrated switching bias supply is a high efficiency step-down regulator that draws only 12 $\mu$ A typical DC supply current with a regulated output voltage at no load.

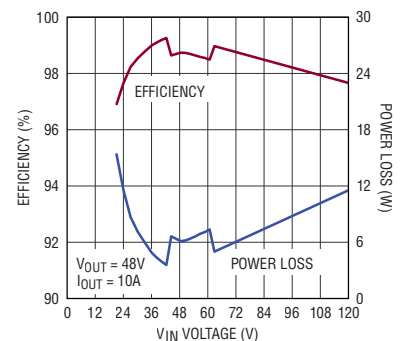
With a wide 4.5V to 150V input and output range and seamless transfers between operating regions, the LTC3777 is ideal for industrial, telecom and battery-powered systems.

The LTC3777 features a power good output indicator and a MODE pin to select between pulse-skipping mode or forced continuous mode of operation. The PLLIN pin allows the IC to be synchronized to an external clock. The SS pin ramps the output voltage during start-up. Current foldback limits MOSFET heat dissipation during short-circuit conditions.

## TYPICAL APPLICATION



Efficiency and Power Loss vs Input Voltage



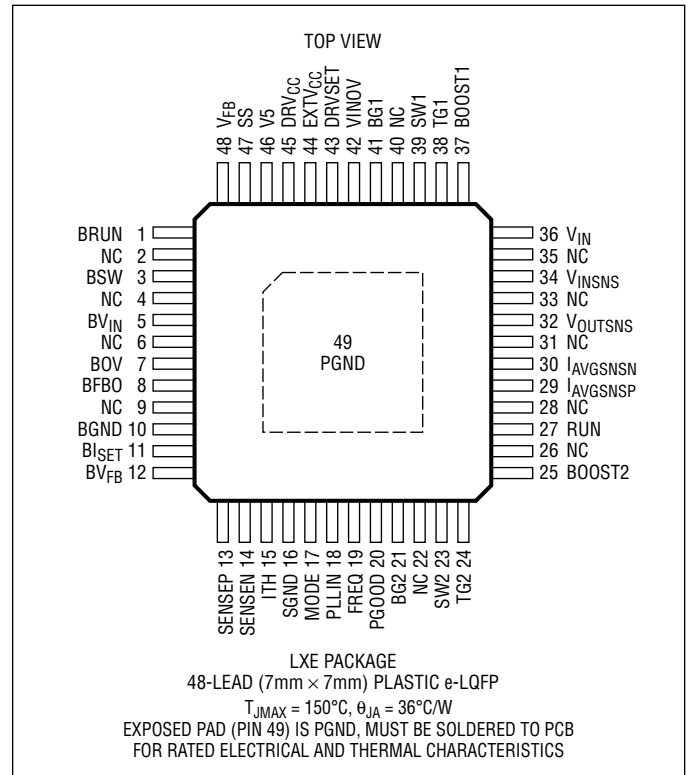
# LTC3777

## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Input Supply Voltage ( $V_{IN}$ ), $BV_{IN}$ .....	150V to -0.3V
Topside Driver Voltage	
BOOST1, BOOST2 .....	161V to -0.3V
Switch Voltage SW1, SW2 .....	150V to -5V
RUN, BRUN .....	150V to -0.3V
$I_{AVGSNSP}$ , $I_{AVGSNSN}$ .....	150V to -10V
$V_{INSNS}$ , $V_{OUTSNS}$ .....	150V to -0.3V
EXTV <sub>CC</sub> Voltage .....	36V to -0.3V
DRV <sub>CC</sub> Voltage .....	11V to -0.3V
BOOST1-SW1, BOOST2-SW2.....	11V to -0.3V
TG1-SW1, TG2-SW2, BG1, BG2.....	(Note 8)
$V_5$ , BOV, BFBO, $BV_{FB}$ , $BI_{SET}$ Voltage .....	6V to -0.3V
MODE, PLLIN, SS, PGOOD .....	V5 to -0.3V
ITH, FREQ, DRVSET .....	V5 to -0.3V
SENSEP, SENSEN, VINOV .....	V5 to -0.3V
$V_{FB}$ Voltage .....	2.7V to -0.3V
Operating Junction Temperature	
Range (Notes 2, 3).....	-40°C to 150°C
Storage Temperature Range .....	-65°C to 150°C
EXTV <sub>CC</sub> /DRV <sub>CC</sub> Peak Current .....	100mA

## PIN CONFIGURATION



## ORDER INFORMATION <http://www.linear.com/product/LTC3777#orderinfo>

LEAD FREE FINISH	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC3777ELXE#PBF	LTC3777 LXE	48-Lead (7mm × 7mm) Plastic e-LQFP	-40°C to 125°C
LTC3777ILXE#PBF	LTC3777 LXE	48-Lead (7mm × 7mm) Plastic e-LQFP	-40°C to 125°C

Consult ADI Marketing for parts specified with wider operating temperature ranges.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>  
LXE package and tray drawings: <http://www.linear.com/packaging>

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the specified operating junction temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$  (Note 2),  $V_{IN} = 15\text{V}$ ,  $V_{RUN} = 5\text{V}$ ,  $V_{EXTVCC} = 0\text{V}$ ,  $V_{DRVSET} = 0\text{V}$ ,  $V_{VINOV} = 0\text{V}$  unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
$V_{IN}$	Input Supply Operating Voltage Range	(Note 4)	4.5		150	V	
$V_{OUT}$	Output Supply Operating Voltage Range		1.2		150	V	
	Regulated Feedback Voltage	(Note 5); ITH Voltage = 1.4V	● 1.188	1.2	1.212	V	
	Feedback Current	(Note 5)		-15	-50	nA	
	Reference Voltage Line Regulation	(Note 5); $V_{IN} = 7\text{V}$ to $100\text{V}$		0.02	0.2	%	
	Output Voltage Load Regulation	(Note 5); Measured in Servo Loop; $\Delta\text{ITH}$ Voltage = 1.5V to 2V	●		0.01	0.2	%
	Transconductance Amplifier gm	(Note 5); ITH = 1.4V; Sink/Source 5 $\mu\text{A}$			1.5		mmho
$I_Q$	Input DC Supply Current	(Note 6)		3.6	5.5	mA	
	Shutdown	RUN = 0V		40	75	$\mu\text{A}$	
	Undervoltage Lockout	V5 Ramping Up		4.1	4.35	4.6	V
		V5 Ramping Down		3.6	3.85	4.1	V
	RUN Pin ON Threshold	$V_{RUN}$ Rising		1.1	1.2	1.3	V
	RUN Pin Hysteresis			100		mV	
	RUN Pin Source Current	$V_{RUN} < 1.2\text{V}$		2.5		$\mu\text{A}$	
	RUN Pin Hysteresis Current	$V_{RUN} > 1.2\text{V}$		6.5		$\mu\text{A}$	
	$V_{IN}$ Overvoltage Lockout Threshold (Rising)	$V_{VINOV}$ Rising		1.18	1.28	1.38	V
	$V_{IN}$ Overvoltage Hysteresis			50		mV	
SENSE Pins Current	$V_{SENSEP} = V_{SENSEN} = 0$				$\pm 2$	$\mu\text{A}$	
$I_{AVGSNSP}$ $I_{AVGSNSN}$	$I_{AVGSNS}$ Pins Current	$V_{I_{AVGSNSP}} = V_{I_{AVGSNSN}} = 10\text{V}$			15	$\mu\text{A}$	
	Soft-Start Charge Current	$V_{SS} = 0\text{V}$	4	5	6	$\mu\text{A}$	
$V_{SENSE(MAX)}$	Maximum Current Sense Threshold (Buck Region Valley Current Mode)	$V_{FB} = 1\text{V}$	● 70	90	110	mV	
	Maximum Current Sense Threshold (Boost Region Peak Current Mode)	$V_{FB} = 1\text{V}$	● 120	140	160	mV	
	Maximum Input / Output Average Current Sense Threshold	$V_{I_{AVGSNSP}} = V_{I_{AVGSNSN}} = 10\text{V}$ , $V_{FB} = 1\text{V}$		47.5	50	52.5	mV
$DC_{(MAX, BOOST)}$	Maximum Duty Factor	% Switch C On		90		%	
$DC_{(MIN, BOOST)}$	Minimum Duty Factor for Main Switch in Boost Operation	% Switch C On		9		%	
$DC_{(MIN, BUCK)}$	Minimum Duty Factor for Main Switch in Buck Operation	% Switch B On		9		%	
<b>Gate Driver</b>							
	TG Pull-Up On Resistance TG Pull-Down On Resistance	$V_{DRVCC} = 6\text{V}$		3.1 1.5		$\Omega$	
	BG Pull-Up On Resistance BG Pull-Down On Resistance	$V_{DRVCC} = 6\text{V}$		5.5 3		$\Omega$	
	TG Transition Time: Rise Time Fall Time	$V_{DRVCC} = 6\text{V}$ (Note 7) $C_{LOAD} = 3300\text{pF}$		60		ns	
	BG Transition Time: Rise Time Fall Time	$V_{DRVCC} = 6\text{V}$ (Note 7) $C_{LOAD} = 3300\text{pF}$		60		ns	

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the specified operating junction temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$  (Note 2),  $V_{IN} = 15\text{V}$ ,  $V_{RUN} = 5\text{V}$ ,  $V_{EXTVCC} = 0\text{V}$ ,  $V_{DRVSET} = 0\text{V}$ ,  $V_{VINOV} = 0\text{V}$  unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
	Top Gate Off to Bottom Gate On Delay Synchronous Switch-On Delay Time	$C_{LOAD} = 3300\text{pF}$ Each Driver, $V_{DRVCC} = 6\text{V}$		60		ns
	Bottom Gate Off to Top Gate On Delay Top Switch-On Delay Time	$C_{LOAD} = 3300\text{pF}$ Each Driver, $V_{DRVCC} = 6\text{V}$		60		ns

**DRV<sub>CC</sub> LDO Regulator**

$V_{DRVCC}$	DRV <sub>CC</sub> Regulation Voltage from Internal $V_{IN}$ LDO	$V_{EXTVCC} = 0\text{V}$ $7\text{V} < V_{IN} < 150\text{V}$ , $V_{DRVSET} = 0\text{V}$ $8\text{V} < V_{IN} < 150\text{V}$ , $V_{DRVSET} = 1/4 V_{V5}$ $9\text{V} < V_{IN} < 150\text{V}$ , $V_{DRVSET} = \text{Float}$ $10\text{V} < V_{IN} < 150\text{V}$ , $V_{DRVSET} = 3/4 V_{V5}$ $11\text{V} < V_{IN} < 150\text{V}$ , $V_{DRVSET} = V_{V5}$		5.5 6.5 7.5 8.45 9.15	5.8 6.8 7.8 8.8 9.5	6.1 7.1 8.1 9.15 9.85	V V V V V
	DRV <sub>CC</sub> Load Regulation from $V_{IN}$ LDO	$I_{CC} = 0\text{mA}$ to $50\text{mA}$ , $V_{EXTVCC} = 0\text{V}$		0.5	2	%	
$V_{EXTVCC}$	DRV <sub>CC</sub> Regulation Voltage from Internal EXTV <sub>CC</sub> LDO	$7\text{V} < V_{EXTVCC} < 30\text{V}$ , $V_{DRVSET} = 0\text{V}$ $8\text{V} < V_{EXTVCC} < 30\text{V}$ , $V_{DRVSET} = 1/4 V_{V5}$ $9\text{V} < V_{EXTVCC} < 30\text{V}$ , $V_{DRVSET} = \text{Float}$ $10\text{V} < V_{EXTVCC} < 30\text{V}$ , $V_{DRVSET} = 3/4 V_{V5}$ $11\text{V} < V_{EXTVCC} < 30\text{V}$ , $V_{DRVSET} = V_{V5}$		5.8 6.8 7.8 8.75 9.65	6.1 7.1 8.1 9.1 10	6.4 7.4 8.4 9.45 10.35	V V V V V
	DRV <sub>CC</sub> Load Regulation from Internal EXTV <sub>CC</sub> LDO	$I_{CC} = 0\text{mA}$ to $50\text{mA}$ , $V_{EXTVCC} = 12\text{V}$ $V_{DRVSET} = 0\text{V}$		0.5	2	%	
	EXTV <sub>CC</sub> LDO Switchover Voltage	EXTV <sub>CC</sub> Ramping Positive		DRV <sub>CC</sub> - 0.5		V	
	EXTV <sub>CC</sub> Hysteresis	% of DRV <sub>CC</sub> Regulation Voltage		10		%	

**V5 Linear Regulator**

	V5 Regulation Voltage	$6\text{V} < V_{DRVCC} < 10\text{V}$		5.3	5.5	5.7	V
	V5 Load Regulation	$I_{V5} = 0\text{mA}$ to $20\text{mA}$ , $V_{DRVCC} = 7\text{V}$		0.5	1	%	

**Oscillator and Phase-Locked Loop**

	Nominal Frequency	$R_{FREQ} = 68.5\text{k}\Omega$		225	250	275	kHz
	Low Fixed Frequency	$R_{FREQ} \leq 20\text{k}\Omega$		30	40	50	kHz
	High Fixed Frequency	$R_{FREQ} = 135\text{k}\Omega$		450	500	550	kHz
	PLLIN Input Threshold	$V_{PLLIN}$ Rising $V_{PLLIN}$ Falling		2		1.2	V V
	PLLIN Input Resistance			200			k $\Omega$
	Synchronizable Oscillator Frequency	PLLIN = External Clock	●	50		600	kHz
$I_{FREQ}$	Frequency Setting Current		●	18	20	22	$\mu\text{A}$

**PGOOD Output**

	PGOOD Voltage Low	$I_{PGOOD} = 2\text{mA}$		0.1	0.3		V
	PGOOD Leakage Current	$V_{PGOOD} = 5.5\text{V}$			$\pm 1$		$\mu\text{A}$
	PGOOD Trip Level	$V_{FB}$ with Respect to Set Regulated Voltage					
		$V_{FB}$ Ramping Negative		-10			%
		$V_{FB}$ Ramping Positive		10			%
	PGOOD delay	$V_{PGOOD}$ High to Low		125			$\mu\text{s}$

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified operating junction temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$  (Note 2).  $V_{IN} = 12\text{V}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>Switching Bias Supply</b>						
$V_{BVIN}$	Input Voltage Operating Range		4		150	V
$V_{BVOUT}$	Output Voltage Operating Range		0.8		$V_{IN}$	V
$BUVLO$	$BV_{IN}$ Undervoltage Lockout	$BV_{IN}$ Rising	3.5	3.8	4.15	V
		$BV_{IN}$ Falling Hysteresis	3.3	3.6 250	3.95	V mV
$I_{QB}$	DC Supply Current (Note 6) Active Mode Sleep Mode Shutdown Mode	No Load $BV_{RUN} = 0\text{V}$		150	350	$\mu\text{A}$
				12	22	$\mu\text{A}$
				1.4	6	$\mu\text{A}$
$V_{BRUN}$	BRUN Pin Threshold	BRUN Rising	1.1	1.2	1.3	V
		BRUN Falling	0.99	1.09	1.19	V
		Hysteresis		110		mV
$I_{BRUN}$	BRUN Pin Leakage Current	$BRUN = 1.3\text{V}$ (Note 9)	-10	0	10	nA
$V_{BOV}$	BOV Pin Threshold	BOV Rising	1.1	1.2	1.3	V
		BOV Falling	0.99	1.09	1.19	V
		Hysteresis		110		mV
<b>Output Supply (<math>BV_{FB}</math>)</b>						
$V_{BVFB}$	Feedback Comparator Threshold	$BV_{FB}$ Rising	0.786	0.800	0.814	V
$V_{BVFBH}$	Feedback Comparator Hysteresis	$BV_{FB}$ Falling	3	5	9	mV
$I_{BVFB}$	Feedback Pin Current	$BV_{FB} = 1\text{V}$ (Note 9)	-10	0	10	nA
<b>Operation</b>						
$I_{PEAKB}$	Peak Current Comparator Threshold	$BI_{SET}$ Floating	170	240	310	mA
		$BI_{SET}$ Shorted to GND	17	25	33	mA
$I_{LBSWB}$	Switch Pin Leakage Current	$BV_{IN} = 150\text{V}$ , $BSW = 0\text{V}$		0.1	1	$\mu\text{A}$
$t_{INT(SS)B}$	Internal Soft-Start Time	(Note 9)		1		ms

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The LTC3777 is tested under pulsed load conditions such that  $T_J \approx T_A$ . The LTC3777E is guaranteed to meet performance specifications from  $0^\circ\text{C}$  to  $85^\circ\text{C}$  junction temperature. Specifications over the  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  operating junction temperature range are assured by design, characterization and correlation with statistical process controls. The LTC3777I is guaranteed over the full  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  operating junction temperature range. Note that the maximum ambient temperature consistent with these specifications is determined by specific operating conditions in conjunction with board layout, the rated package thermal impedance and other environmental factors. The junction temperature  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the formula:

$$T_J = T_A + (P_D \cdot \theta_{JA}),$$

where  $\theta_{JA} = 36^\circ\text{C/W}$  for the e-LQFP package.

**Note 3:** This IC includes over temperature protection that is intended to protect the device during momentary overload conditions. The maximum rated junction temperature will be exceeded when this protection is active.

Continuous operation above the specified absolute maximum operating junction temperature may impair device reliability or permanently damage the device.

**Note 4:** When biased from an auxiliary supply through the  $EXTV_{CC}$  pin, the LTC3777 can operate from a  $V_{IN}$  voltage lower than 4.5V. Otherwise the minimum  $V_{IN}$  operational voltage is 4.5V after startup.

**Note 5:** The LTC3777 is tested in a feedback loop that servos  $V_{ITH}$  to a specified voltage and measures the resultant  $V_{FB}$ .

**Note 6:** Dynamic supply current is higher due to the gate charge being delivered at the switching frequency. See Applications information.

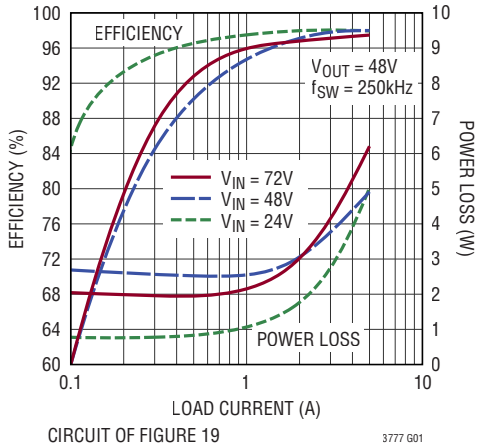
**Note 7:** Rise and fall times are measured using 10% and 90% levels. Delay times are measured using 50% levels.

**Note 8:** Do not apply a voltage or current source to these pins. They must be connected to capacitive loads only, otherwise permanent damage may occur. These pins are rated for an absolute maximum voltage of  $-0.3\text{V}$  to  $11\text{V}$ .

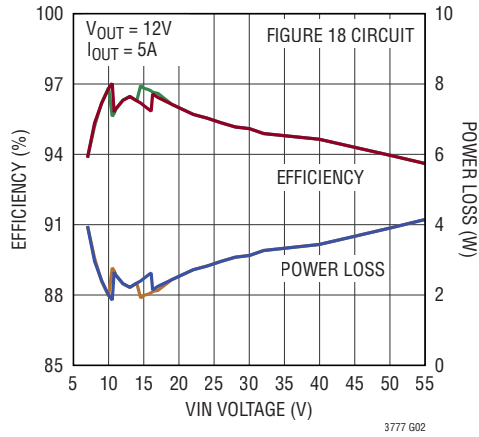
**Note 9:** Guaranteed by design and wafer level measurements.

**TYPICAL PERFORMANCE CHARACTERISTICS**

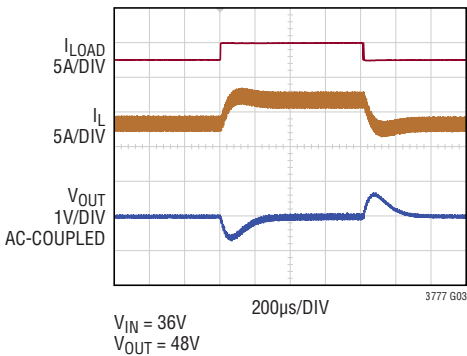
**Efficiency and Power Loss vs Load Current and Input Voltage  
Continuous Mode**



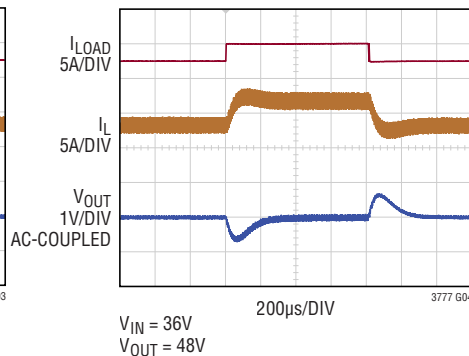
**Efficiency and Power Loss vs Input Voltage**



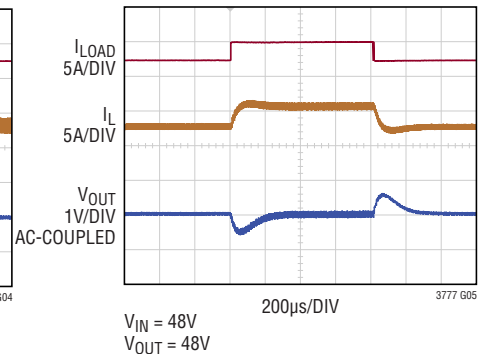
**Load Step Boost Region  
Continuous Mode**



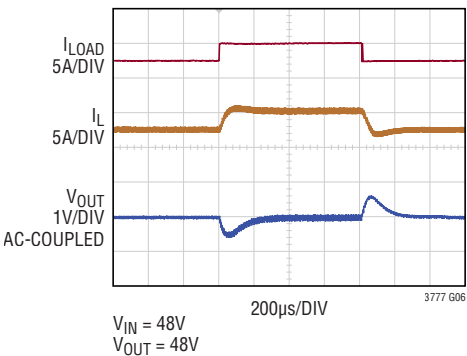
**Load Step Boost Region  
Pulse-Skipping Mode**



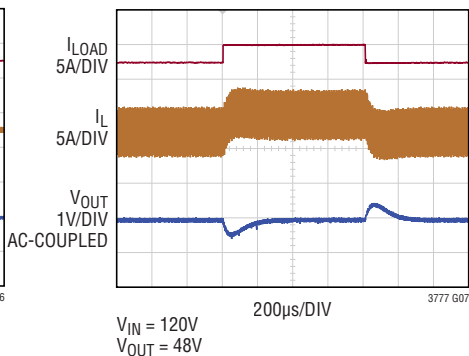
**Load Step Buck-Boost Region  
Continuous Mode**



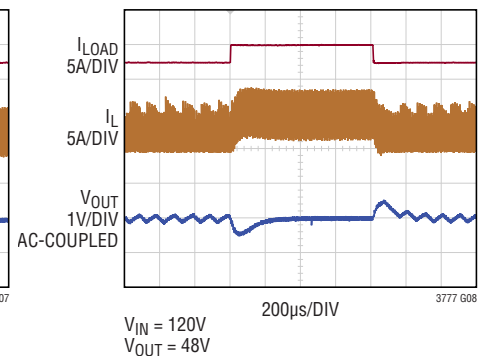
**Load Step Buck-Boost Region  
Pulse-Skipping Mode**



**Load Step Buck Region  
Continuous Mode**

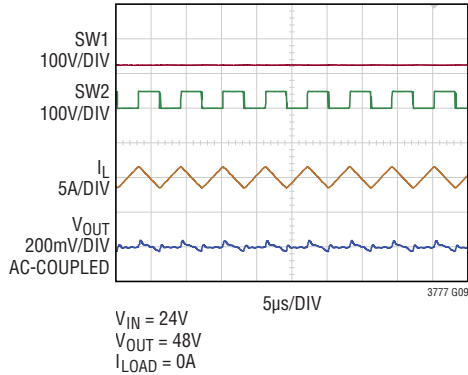


**Load Step Buck Region  
Pulse-Skipping Mode**

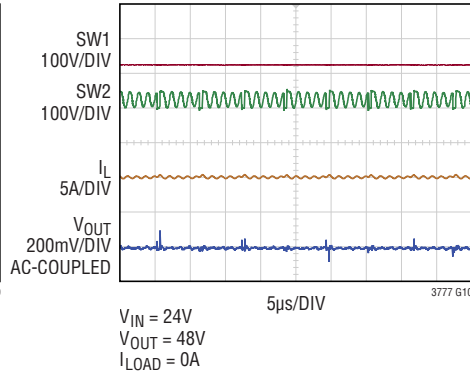


# TYPICAL PERFORMANCE CHARACTERISTICS

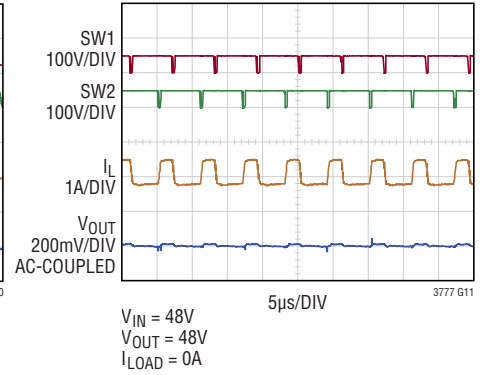
**Forced Continuous Mode Boost Region**



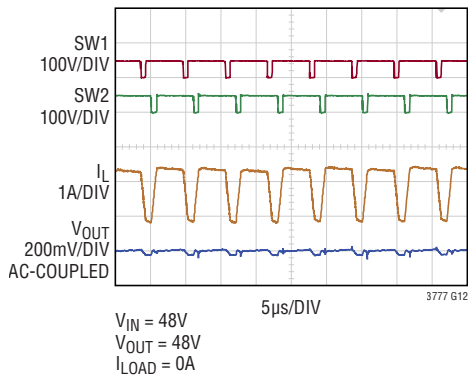
**Pulse-Skipping Mode Boost Region**



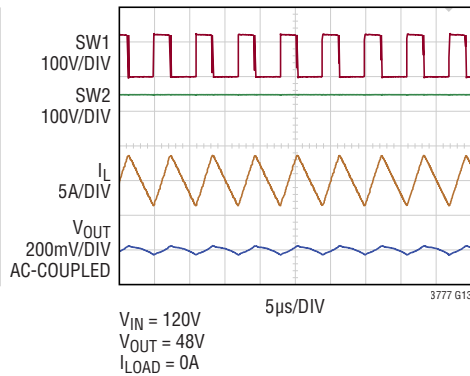
**Forced Continuous Mode Buck-Boost Region**



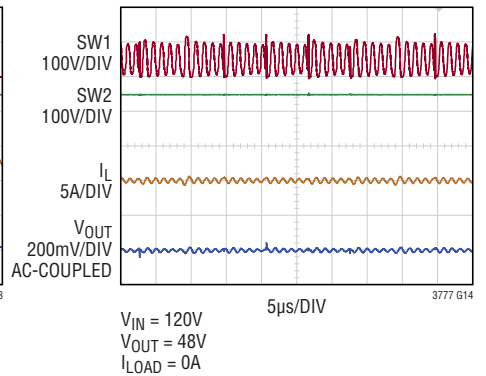
**Pulse-Skipping Mode Buck-Boost Region**



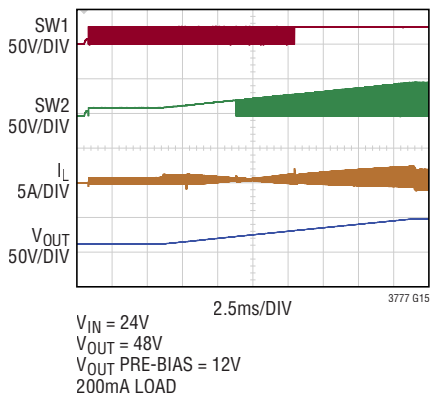
**Forced Continuous Mode Buck Region**



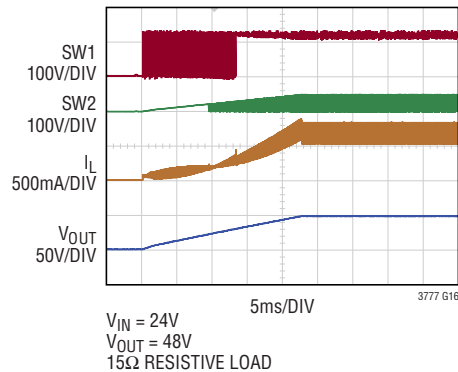
**Pulse-Skipping Mode Buck Region**



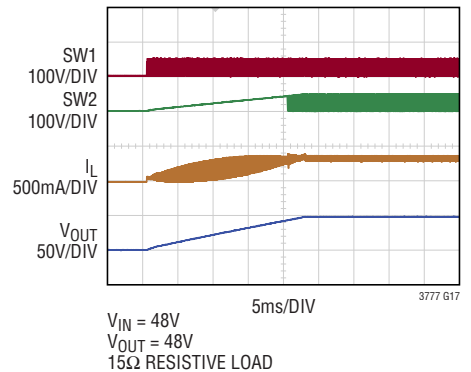
**Start-Up from RUN Forced Continuous Mode Pre-Biased Output**



**Start-Up Forced Continuous Mode Boost Region**

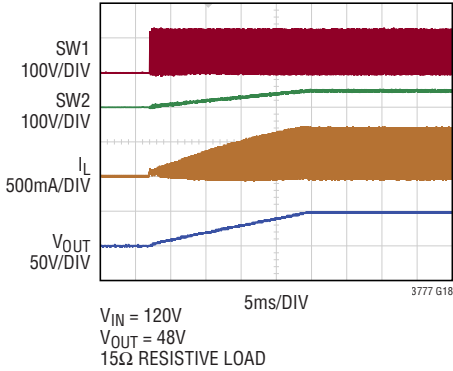


**Start-Up Forced Continuous Mode Buck-Boost Region**

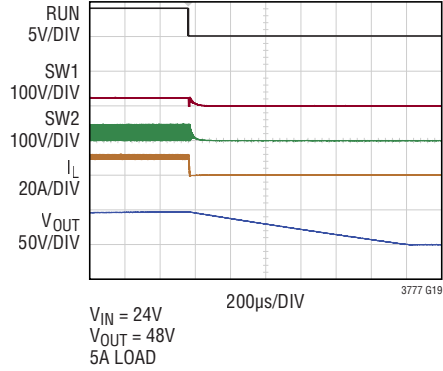


## TYPICAL PERFORMANCE CHARACTERISTICS

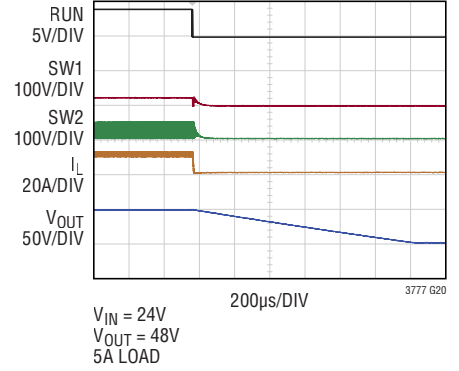
**Start-Up Forced Continuous Mode Buck Region**



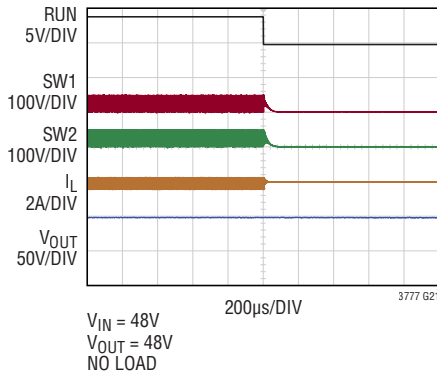
**Shutdown from RUN Forced Continuous Mode Boost Region**



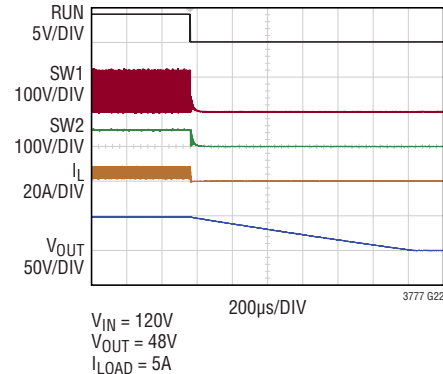
**Shutdown from RUN Pulse-Skipping Mode Boost Region**



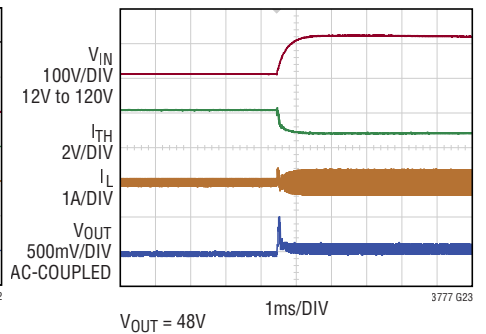
**Shutdown from RUN Forced Continuous Mode Buck-Boost Region**



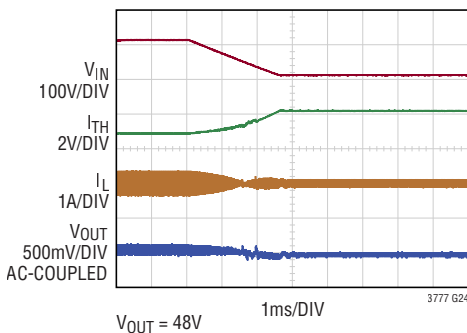
**Shutdown from RUN Forced Continuous Mode Buck Region**



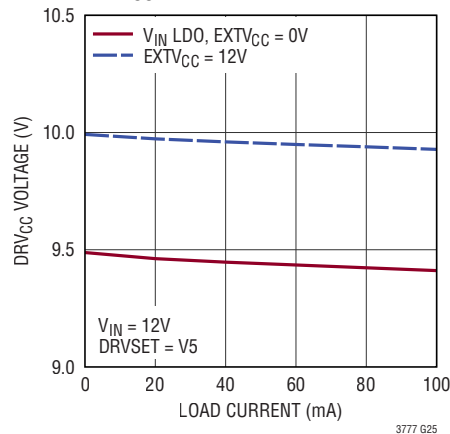
**Line Transient Rising Edge**



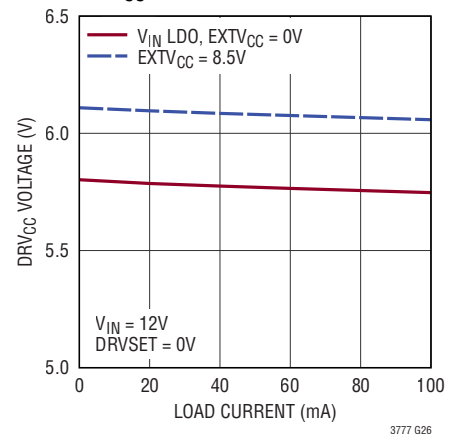
**Line Transient Falling Edge**



**DRV<sub>CC</sub> vs Load Current**



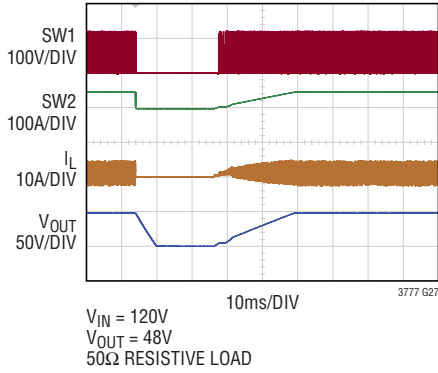
**DRV<sub>CC</sub> vs Load Current**



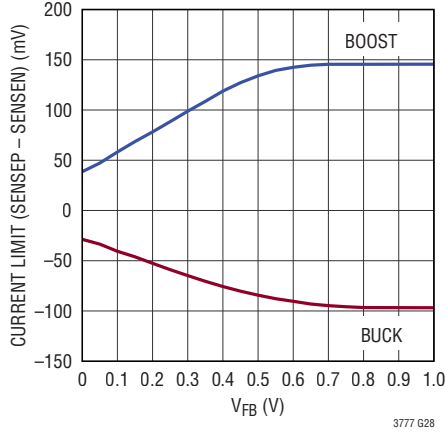


# TYPICAL PERFORMANCE CHARACTERISTICS

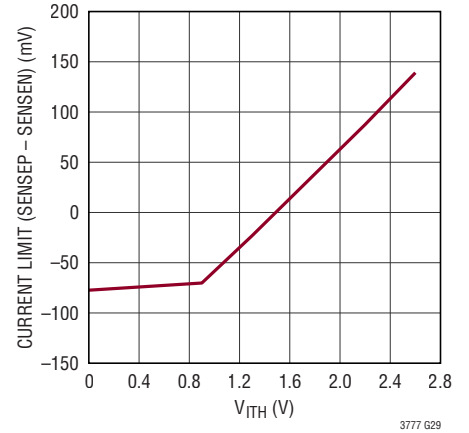
**VINOV Transient Forced Continuous Mode Buck Region**



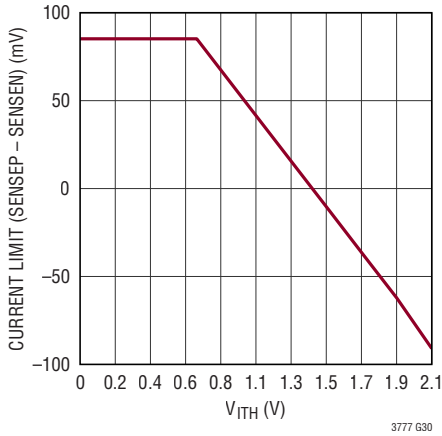
**Current Foldback Limit**



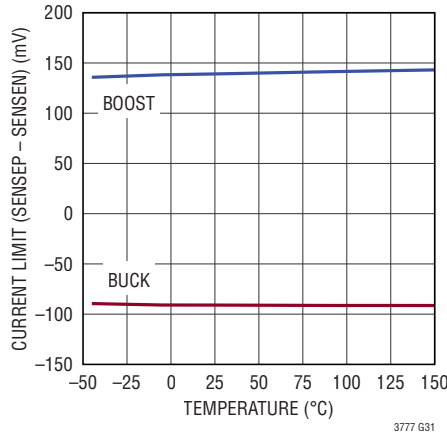
**Peak Current Threshold vs  $V_{ITH}$  (Boost)**



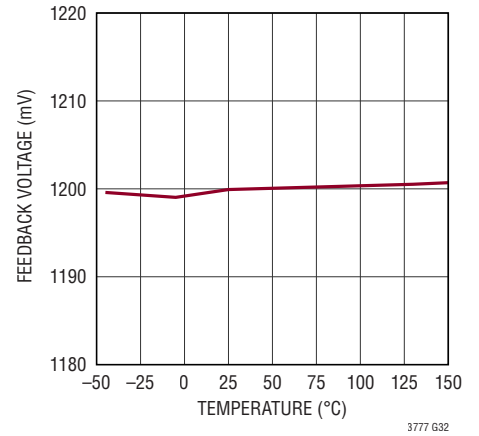
**Valley Current Threshold vs  $V_{ITH}$  (Buck)**



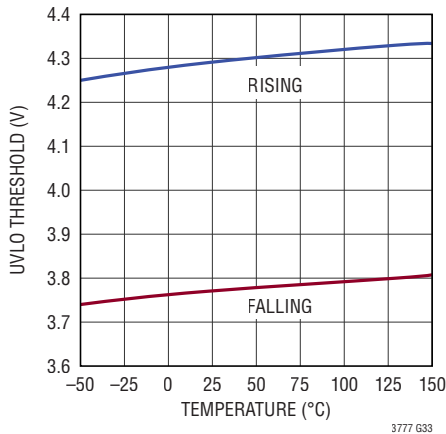
**Maximum Current Limit vs Temperature**



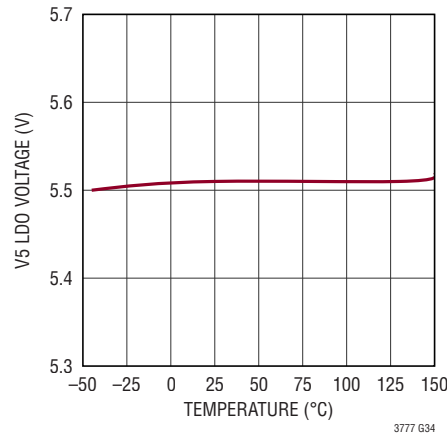
**Regulated Feedback Voltage vs Temperature**



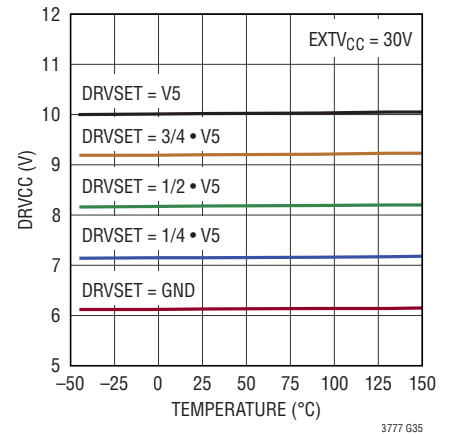
**Undervoltage Lockout Threshold (V5) vs Temperature**



**V5 Low Dropout Regulation Voltage vs Temperature**

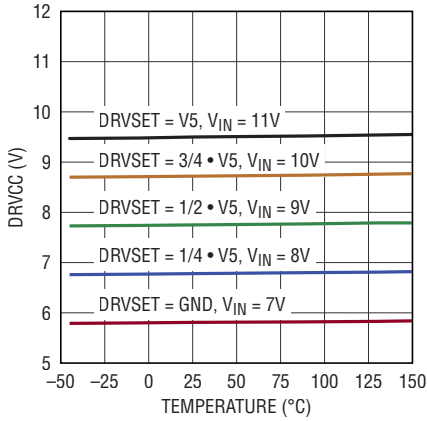


**EXTVCC LDO vs Temperature**

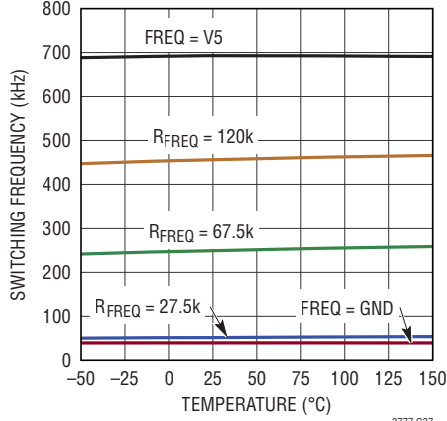


## TYPICAL PERFORMANCE CHARACTERISTICS

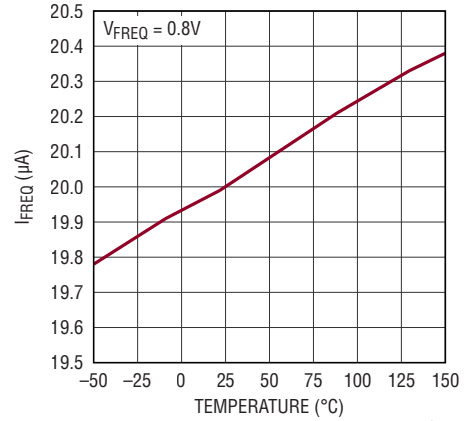
### V<sub>IN</sub> LDO vs Temperature



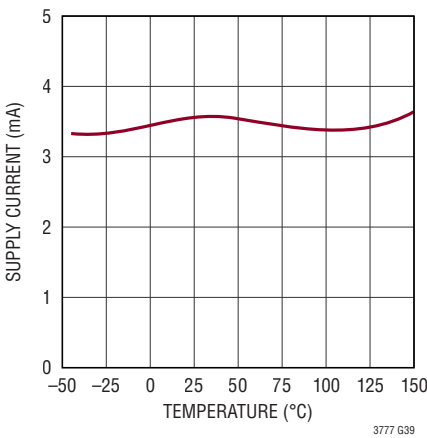
### Oscillator Frequency vs Temperature



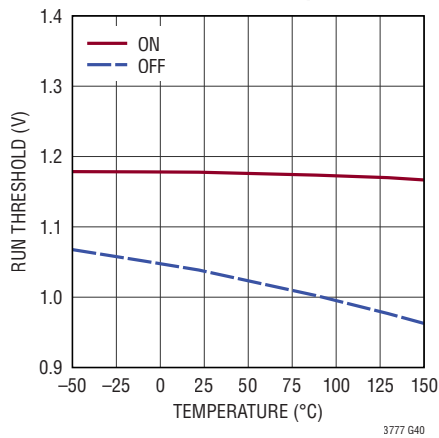
### Frequency Setting Current vs Temperature



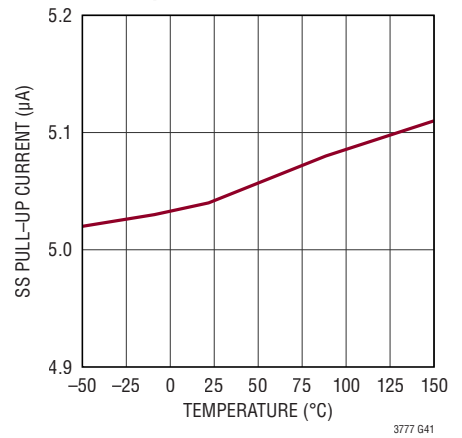
### Input Supply Current vs Temperature



### RUN Threshold vs Temperature

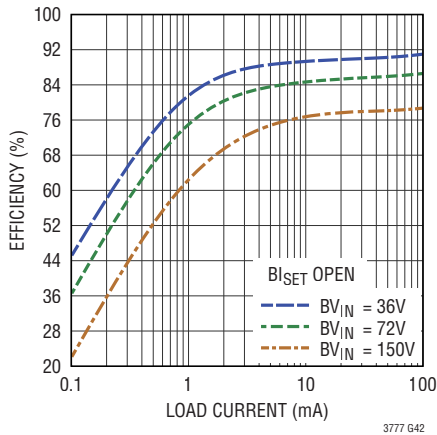


### Soft-Start Pull-Up Current vs Temperature

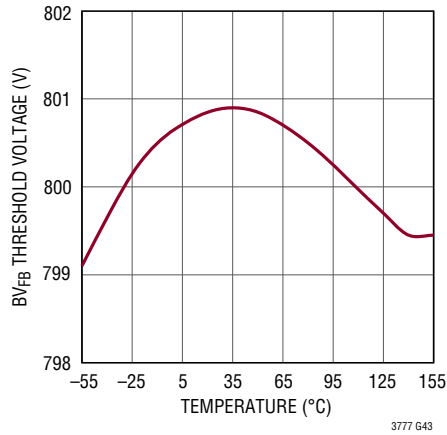


# TYPICAL PERFORMANCE CHARACTERISTICS – SWITCHING BIAS SUPPLY

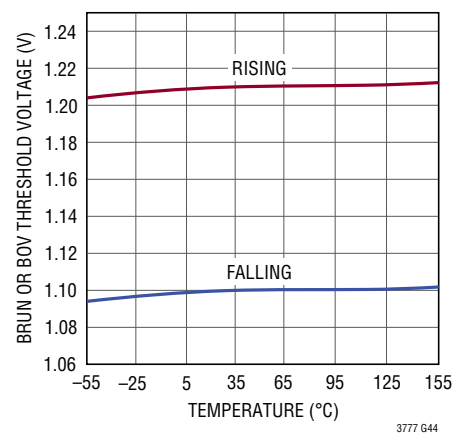
**Efficiency vs Load Current,  $BV_{OUT} = 12V$**



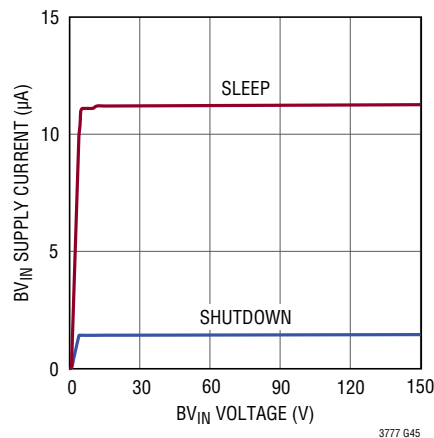
**Feedback Comparator Trip Threshold vs Temperature**



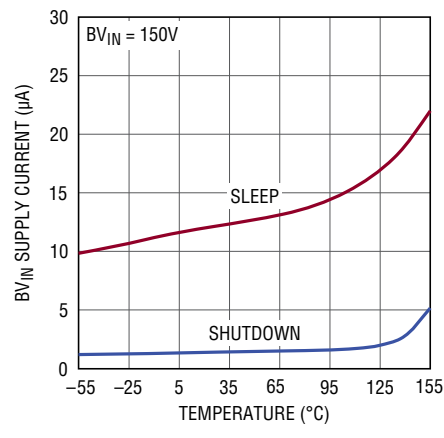
**BRUN and BOV Comparator Threshold vs Temperature**



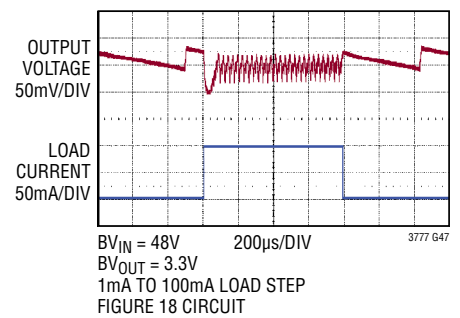
**Quiescent Supply Current vs Input Voltage**



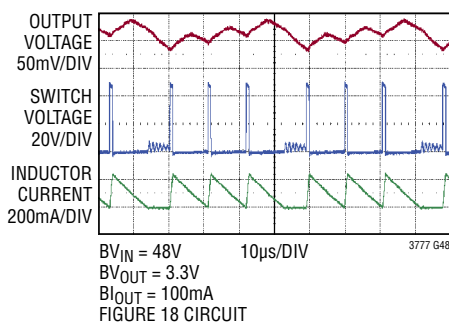
**Quiescent Supply Current vs Temperature**



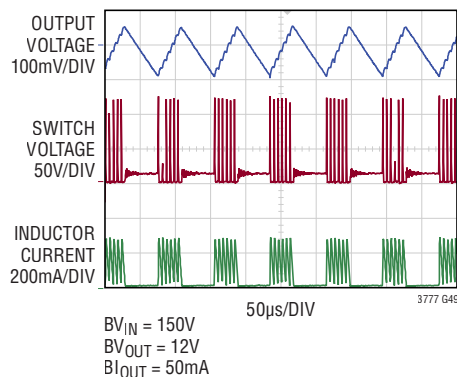
**Load Step Transient Response**



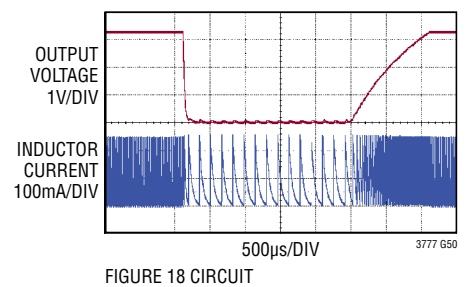
**Operating Waveforms,  $BV_{IN} = 48V$**



**Operating Waveforms,  $BV_{IN} = 150V$**



**Short-Circuit and Recovery**



## PIN FUNCTIONS

**BRUN (Pin 1):** Bias Supply Run Control Input. A voltage on this pin above 1.21V enables normal operation. Forcing this pin below 0.7V shuts down the switching bias supply, reducing quiescent current to approximately 1.4 $\mu$ A. Optionally, connect to the input supply through a resistor divider to set the undervoltage lockout.

**BSW (Pin 3):** Bias Supply Switch Node Connection to Inductor. This pin connects to the drains of the internal power MOSFET switches.

**BVIN (Pin 5):** Bias Supply Main Supply Pin. A ceramic bypass capacitor should be tied between this pin and GND.

**BOV (Pin 7):** Bias Supply Overvoltage Lockout Input. Connect to the input supply through a resistor divider to set the overvoltage lockout level. A voltage on this pin above 1.21V disables the internal MOSFET switches. Normal operation resumes when the voltage on this pin decreases below 1.10V. Exceeding the OVLO lockout threshold triggers a soft-start reset, resulting in a graceful recovery from an input supply transient. Tie this pin to ground if the overvoltage is not used.

**BFBO (Pin 8):** Bias Supply Feedback Comparator Output. The typical pull-up current is 20 $\mu$ A. The typical pull-down impedance is 70 $\Omega$ . This output signal can be used to synchronize other ICs.

**BGND (Pin 10):** Ground.

**BISET (Pin 11):** Bias Supply Peak Current Set Input. Leave floating for the maximum peak current (230mA typical) or short to ground for minimum peak current (25mA typical). The maximum output current is one-half the peak current.

**BVFB (Pin 12):** Bias Supply Output Voltage Feedback. Connect to an external resistive divider to divide the output voltage down for comparison to the 0.8V reference.

**SENSEP (Pin 13):** The positive input to the differential current comparator. This pin is normally connected to a sense resistor at the source of the power MOSFET. The ITH pin voltage and controlled offsets between the SENSEP and SENSEN pins, in conjunction with  $R_{SENSE}$ , set the current trip threshold.

**SENSEN (Pin 14):** The negative input to the differential current sense comparator. This pin is normally connected to the ground side of the sense resistor.

**ITH (Pin 15):** Error Amplifier Output. The current comparator trip threshold increases with the ITH control voltage. The ITH pin is also used for compensating the control loop of the converter.

**SGND (Pin 16):** Signal ground. All feedback and soft-start connections should return to SGND. For optimum load regulation, the SGND pin should be Kelvin connected to the PCB location between the negative terminals of the output capacitors.

**MODE (Pin 17):** Mode Selection pin. Tying this pin to SGND or below 0.8V enables forced continuous mode. Tying it to V5 enables pulse-skipping mode.

**PLLIN (Pin 18):** External Synchronization Input to Phase Detector. For external sync, apply a clock signal to this pin and the internal PLL will synchronize the internal oscillator to the clock. The PLL compensation network is integrated into the IC. When synchronized to an external clock, the regulator can operate either in forced continuous or pulse-skipping mode. The mode of operation is controlled by the setting on the MODE pin.

**FREQ (Pin 19):** The frequency control pin for the internal VCO. Frequencies between 40kHz and 500kHz can be programmed by using a resistor between FREQ and SGND. The resistor and an internal 20 $\mu$ A source current create a voltage used by the internal oscillator to set the frequency.

**PGOOD (Pin 20):** Fault indicator Output. Open-drain output that pulls to ground when the voltage on the  $V_{FB}$  pin is not within  $\pm 10\%$  of its set point.

**BG1/BG2 (Pins 41 and 21):** Bottom Gate Driver Outputs. This pin drives the gate(s) of the bottom N-Channel MOSFET between PGND to  $DRV_{CC}$ .

**SW1, SW2 (Pins 39 and 23):** Switch Node Connections to the Inductors.

## PIN FUNCTIONS

**TG1, TG2 (Pin 38 and 24):** High Current Gate Drives for Top N-Channel MOSFETs. These are the outputs of floating high side drivers with a voltage swing equal to  $DRV_{CC}$  superimposed on the switch node voltage SW.

**BOOST1, BOOST2 (Pin 37 and 25):** Boosted Floating Driver Supplies. The (+) terminal of the bootstrap capacitor connects to this pin. This pin swings from a diode drop below  $DRV_{CC}$  up to  $V_{IN} + DRV_{CC}$ .

**RUN (Pin 27):** Enable Control Input. A voltage above 1.2V turns on the IC. There is a 2.5 $\mu$ A pull-up current on this pin. Once the RUN pin rises above the 1.2V threshold the pull-up current increases to 6.5 $\mu$ A. Forcing this pin below 1.1V shuts down the controller. This pin can be tied to  $V_{IN}$  for always-on operation. Do not float this pin.

**$I_{AVGSNSP}$  (Pin 29):** The positive input to the Input / Output Average Current Sense Amplifier.

**$I_{AVGSNSN}$  (Pin 30):** The negative input to the Input / Output Average Current Sense Amplifier. Short  $I_{AVGSNSP}$  and  $I_{AVGSNSN}$  pins together, and tie them to V5, if this average current loop function is not used.

**$V_{OUTSNS}$  (Pin 32):**  $V_{OUT}$  Sense Input to the Buck-Boost Transition comparator. Connect this pin to the drain of the top N-channel MOSFET on the output side through a 1k $\Omega$  resistor.

**$V_{INSNS}$  (Pin 34):**  $V_{IN}$  Sense Input to the Buck-Boost Transition comparator. Connect this pin to the drain of the top N-channel MOSFET on the input side.

**$V_{IN}$  (Pin 36):** Main Supply Pin. A bypass capacitor should be tied between this pin and the PGND pin.

**VINOV (Pin 42):** Connect to the input supply through a resistor divider to set the over-voltage lockout level. A voltage on this pin above 1.28V disables all switching, and the top GATE pins are held low, the bottom GATE pins are held high, and  $V_{OUT}$  is disconnected from  $V_{IN}$ .  $DRV_{CC}$  and V5 regulation is maintained during an over-voltage event. Normal operation resumes when the voltage on this pin decreases below 1.23V. Exceeding the VINOV lockout

threshold triggers a soft-start reset, resulting in a graceful recovery from an input supply transient. Tie this pin to ground if the overvoltage function is not used.

**DRVSET (Pin 43):** Sets the regulated output voltage of the  $DRV_{CC}$  linear regulator from 6V to 10V in 1V increments. Tying this pin to SGND sets  $DRV_{CC}$  to 6V, tying it to  $1/4 \cdot V5$  sets  $DRV_{CC}$  to 7V, while floating this pin sets  $DRV_{CC}$  to 8V, tying it to  $3/4 \cdot V5$  sets  $DRV_{CC}$  to 9V, and tying it to V5 sets  $DRV_{CC}$  to 10V.

**EXTV<sub>CC</sub> (Pin 44):** External Power Input to an Internal LDO Connected to  $DRV_{CC}$ . When the voltage on this pin is greater than the  $DRV_{CC}$  LDO setting minus 500mV, this LDO bypasses the internal LDO powered from  $V_{IN}$ . Tie this pin to ground if the EXTV<sub>CC</sub> is not used.

**DRV<sub>CC</sub> (Pin 45):** Output of the Internal or External Low Dropout Regulator. The gate drivers are powered from this voltage source. The  $DRV_{CC}$  voltage is set by the DRVSET pin. A low ESR 4.7 $\mu$ F (X5R or better) ceramic bypass capacitor should be connected between  $DRV_{CC}$  and PGND, as close as possible to the IC. Do not use the  $DRV_{CC}$  pin for any other purpose.

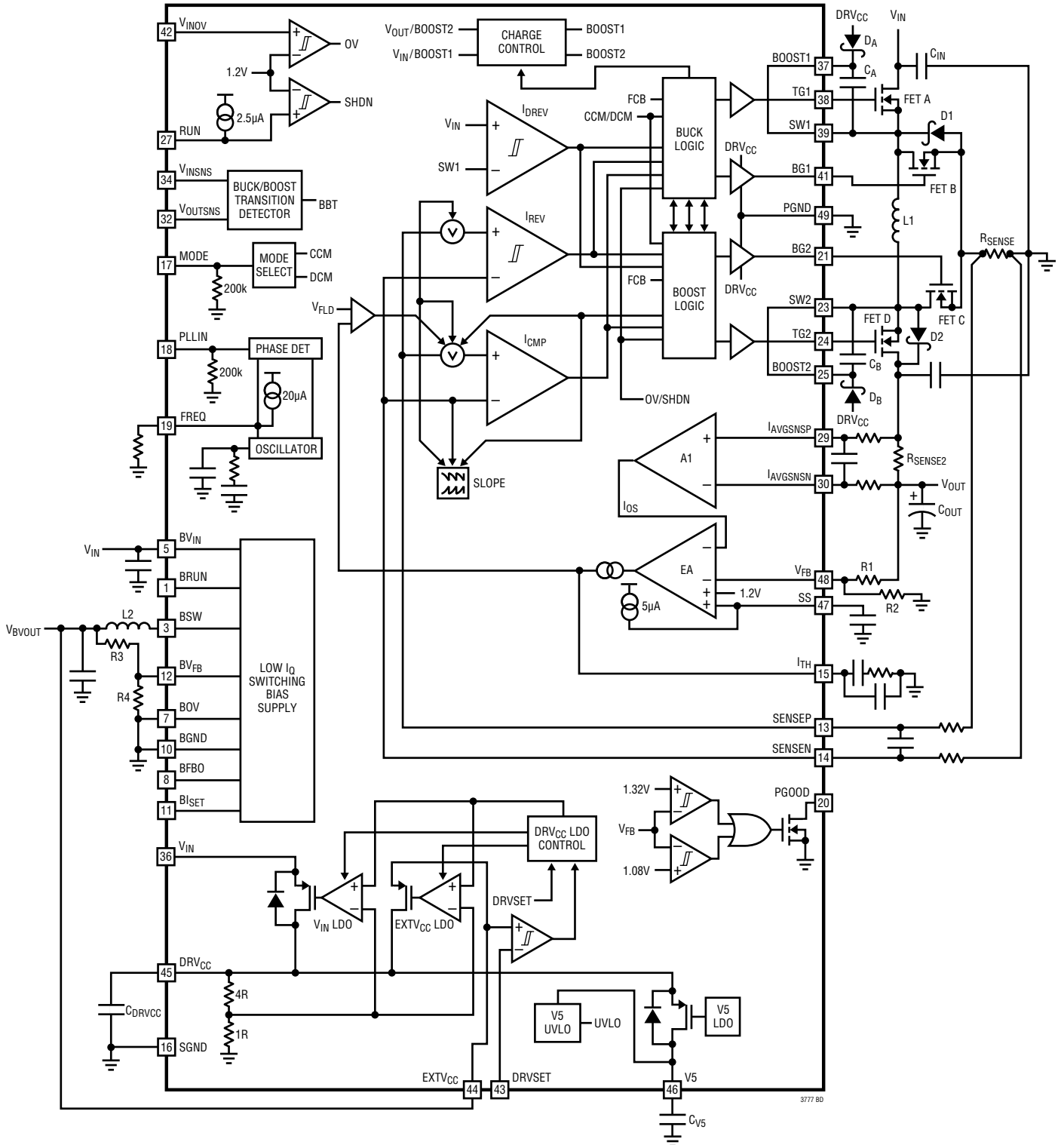
**V5 (Pin 46):** Output of the Internal 5.5V Low Dropout Regulator. The control circuits are powered from this voltage. Bypass this pin to SGND with a minimum of 2.2 $\mu$ F low ESR tantalum or ceramic capacitor, as close as possible to the IC.

**SS (Pin 47):** Soft-Start Input. The voltage ramp rate at this pin sets the voltage ramp rate of the regulated voltage. This pin has a 5 $\mu$ A pull-up current. A capacitor to ground at this pin sets the ramp time to final regulated output voltage.

**V<sub>FB</sub> (Pin 48):** Error Amplifier Input. The FB pin should be connected through a resistive divider network to  $V_{OUT}$  to set the output voltage.

**PGND (Exposed Pad Pin 49):** Driver Power Ground. Connects to the (–) terminal of  $C_{IN}$ ,  $C_{OUT}$  and  $R_{SENSE}$ . The exposed pad must be soldered to PCB ground for electrical contact and rated thermal performance.

**BLOCK DIAGRAM**



3777 BD

## OPERATION

### MAIN CONTROL LOOP

The LTC3777 is a 150V synchronous buck-boost controller with an integrated 150V, 85mA, high efficiency synchronous switching bias supply. The 150V switching bias supply draws only 12 $\mu$ A typical DC supply current while maintaining a regulated output voltage at no load.

The 150V synchronous buck-boost is a current mode controller that provides an output voltage above, equal to or below the input voltage. The ADI proprietary topology and control architecture employs a current-sensing resistor. The inductor current is controlled by the voltage on the I<sub>TH</sub> pin, which is the output of the error amplifier EA. The V<sub>FB</sub> pin receives the voltage feedback signal, which is compared to the internal reference voltage by the EA. If the input/output current regulation loop is implemented, the sensed inductor current is controlled by either the sensed feedback voltage or the input/output current.

### DRV<sub>CC</sub>/EXTV<sub>CC</sub>/V5 Power

Power for the top and bottom MOSFET drivers is derived from the DRV<sub>CC</sub> pin. The DRV<sub>CC</sub> supply voltage can be programmed from 6V to 10V in 1V steps using the DRVSET pin. The internal V<sub>IN</sub> LDO (low dropout linear regulator) can provide power from V<sub>IN</sub> to DRV<sub>CC</sub>. The internal V<sub>IN</sub> LDO uses an internal P-channel pass device between the V<sub>IN</sub> and DRV<sub>CC</sub> pins. To prevent high on-chip power dissipation in high input voltage applications, the LTC3777 also includes an integrated 150V, low I<sub>Q</sub> 85mA synchronous step-down regulator to bias the buck-boost controller. See Integrated Switching Bias Supply in the Operation section for more information.

When the EXTV<sub>CC</sub> pin is tied to a voltage below its switchover voltage (DRV<sub>CC</sub> – 500mV), the V<sub>IN</sub> LDO is enabled and supplies power from V<sub>IN</sub> to DRV<sub>CC</sub>. If EXTV<sub>CC</sub> is taken above its switchover voltage, the V<sub>IN</sub> LDO is turned off and an EXTV<sub>CC</sub> LDO is turned on. Once enabled, the EXTV<sub>CC</sub> LDO supplies power from EXTV<sub>CC</sub> to DRV<sub>CC</sub>. Using the EXTV<sub>CC</sub> pin allows the DRV<sub>CC</sub> power to be derived from a high efficiency supply such as the low I<sub>Q</sub> integrated step-down regulator bias supply or the LTC3777 switching regulator output if the output voltage is less than 36V.

Most of the internal circuitry is powered from the V5 rail that is generated by an internal linear regulator from DRV<sub>CC</sub>. The V5 pin needs to be bypassed with a 1 $\mu$ F to 10 $\mu$ F external capacitor between V5 and SGND. This pin provides a 5.5V output that can supply up to 20mA of current. See the [Applications Information](#) section for more details.

### Top MOSFET DRIVER and Internal Charge Path

Each of the two top MOSFET drivers is biased from its floating bootstrap capacitor, which is normally recharged by DRV<sub>CC</sub> through an external diode when the top MOSFET is turned off and when SW goes low. When the LTC3777 operates exclusively in the buck or boost regions, one of the top MOSFETs is constantly on. An internal charge path, from V<sub>OUT</sub> and BOOST2 to BOOST1 or from V<sub>IN</sub> and BOOST1 to BOOST2, charges the bootstrap capacitor so that the top MOSFET can be kept on. However, if a high leakage external diode is used such that the internal charge path cannot provide sufficient charge to the external bootstrap capacitor, an internal UVLO comparator, which constantly monitors the drop across the capacitor, will sense the (BOOST – SW) voltage when it is below the boost capacitor refresh threshold. This will turn off its top MOSFET for about one-twelfth of the clock period every four cycles to allow the bootstrap capacitor to recharge. The boost capacitor refresh threshold varies with the DRVSET pin setting.

### Shutdown and Start-Up

The LTC3777 can be shut down by pulling the RUN pin low. Pulling RUN below 1.1V shuts down the main control loop for the controller and most internal circuits, including the DRV<sub>CC</sub> and V5 regulators. Releasing RUN allows an internal 2.5 $\mu$ A current to pull-up the pin and enable the controller. When RUN is above the accurate threshold of 1.2V, the internal LDO will power up DRV<sub>CC</sub>. At the same time, a 6.5 $\mu$ A pull-up current will kick in to provide more RUN pin hysteresis. The RUN pin may be externally pulled up or driven directly by logic. The RUN pin can tolerate up to 150V (absolute maximum), so it can be conveniently tied to V<sub>IN</sub> in always-on applications where the controller is enabled continuously and never shut down. The RUN

## OPERATION

pin will have no internal pull-up current when externally driven to a voltage above 4V.

### Soft-Start

The start-up of the controller's output voltage  $V_{OUT}$  is controlled by the voltage on the SS pin. When the voltage on the SS pin is less than the 1.2V internal reference, the LTC3777 regulates the  $V_{FB}$  voltage to the SS voltage instead of the 1.2V reference. This allows the SS pin to be used to program soft-start by connecting an external capacitor from the SS pin to SGND. An internal 5 $\mu$ A pull-up current charges this capacitor, creating a voltage ramp on the SS pin. As the SS voltage rises linearly from 0V to 1.2V (and beyond), the output voltage  $V_{OUT}$  rises smoothly from zero to its final value. When RUN is pulled low to disable the controller, or during an overvoltage event on the  $V_{IN}$  input supply or during an overtemperature shutdown event, or when  $V_5$  drops below its undervoltage lockout threshold of 3.85V, the SS pin is pulled low by an internal MOSFET. When in undervoltage lockout, the controller is disabled and the external MOSFETs are held off.

Certain applications can require the start-up of the converter into a non-zero load voltage, where residual charge is stored on the  $V_{OUT}$  capacitor at the onset of converter switching. In order to prevent the  $V_{OUT}$  from discharging under these conditions, the part will be forced into discontinuous mode of operation until the SS voltage crosses  $V_{FB}$  or 1.32V, whichever is lower.

### Power Switch Control

Figure 1 shows a simplified diagram of how the four power switches are connected to the inductor,  $V_{IN}$ ,  $V_{OUT}$  and GND. Figure 2 shows the regions of operation for the LTC3777 as a function of  $V_{OUT} - V_{IN}$  or switch duty cycle, DC. The power switches are properly controlled so the transfer between regions is continuous. Hysteresis is added to prevent chattering when transitioning between regions.

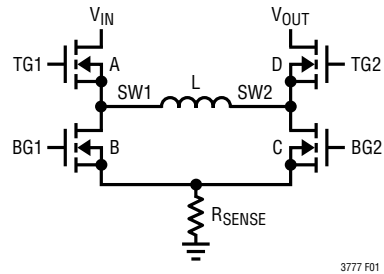


Figure 1. Simplified Diagram of the Output Switches

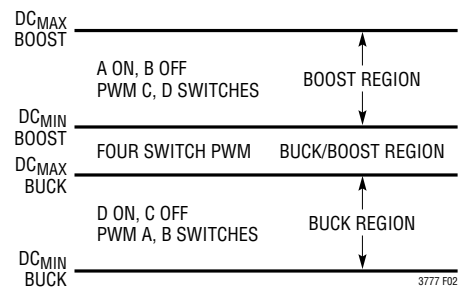


Figure 2. Operating Region vs Duty Cycle

### Buck Region ( $V_{IN} \gg V_{OUT}$ )

When  $V_{IN}$  is significantly higher than  $V_{OUT}$ , the part will run in the buck region. In this region switch C is always off. At the start of every cycle, synchronous switch B is turned on first. Inductor current is sensed when synchronous switch B is turned on. After the sensed inductor valley current falls below a reference voltage, which is proportional to  $V_{ITH}$ , synchronous switch B is turned off and switch A is turned on for the remainder of the cycle. Switches A and B will alternate, behaving like a typical synchronous buck regulator. The duty cycle of Switch A increases until the maximum duty cycle of the converter reaches  $DC_{(MAX\_BUCK)}$ , given by:

$$DC_{(MAX, BUCK)} = \left(1 - \frac{1}{12}\right) \cdot 100\% = 91.67\%$$

Figure 3 shows the typical buck region waveforms. If  $V_{IN}$  approaches  $V_{OUT}$ , the buck-boost region is reached.



## OPERATION

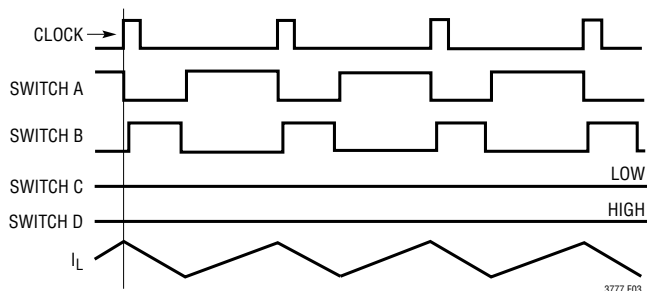
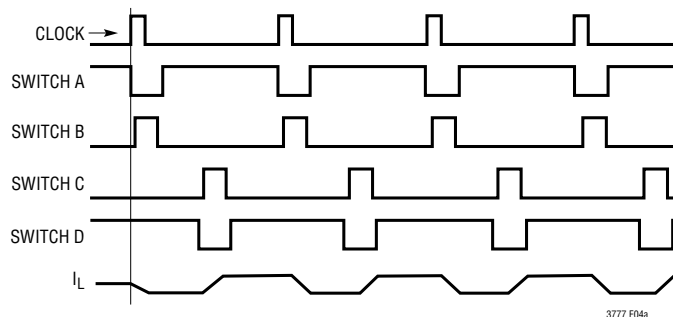


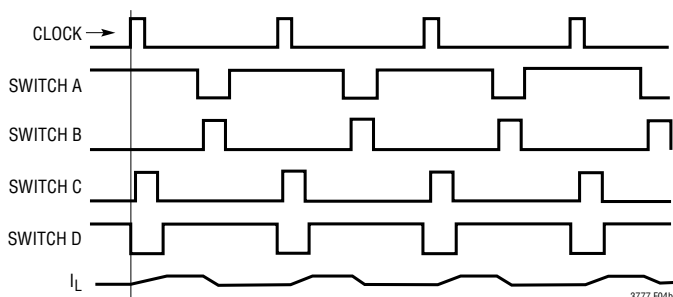
Figure 3. Buck Region ( $V_{IN} \gg V_{OUT}$ )

### Buck-Boost Region ( $V_{IN} \approx V_{OUT}$ )

When  $V_{IN}$  is close to  $V_{OUT}$ , the controller enters the buck-boost region. Figure 4 shows the typical waveforms in this region. At the beginning of a clock cycle, if the controller starts with B and D on, the controller first operates as if in the buck region. When  $I_{CMP}$  trips, switch B is turned off, and switch A is turned on. At  $120^\circ$  clock phase, switch C is turned on. The LTC3777 starts to operate as a boost until  $I_{CMP}$  trips. Then, switch D is turned on for the remainder of the clock period. If the controller starts with switches



(4a) Buck-Boost Region ( $V_{IN} \geq V_{OUT}$ )



(4b) Buck-Boost Region ( $V_{IN} \leq V_{OUT}$ )

Figure 4. Buck-Boost Region

A and C on, the controller first operates as a boost, until  $I_{CMP}$  trips and switch D is turned on. At  $120^\circ$ , switch B is turned on, making it operate as a buck. Then,  $I_{CMP}$  trips, turning switch B off and switch A on for the remainder of the clock period.

### Boost Region ( $V_{IN} \ll V_{OUT}$ )

Switch A is always on and synchronous switch B is always off in the boost region. In every cycle, switch C is turned on first. Inductor current is sensed when synchronous switch C is turned on. After the sensed inductor peak current exceeds what the reference voltage demands, which is proportional to  $V_{ITH}$ , switch C is turned off and synchronous switch D is turned on for the remainder of the cycle. Switches C and D will alternate, behaving like a typical synchronous boost regulator.

The duty cycle of switch C decreases until the minimum duty cycle of the converter reaches  $DC_{(MIN,BOOST)}$ , given by:

$$DC_{(MIN,BOOST)} = \left( \frac{1}{12} \right) \cdot 100\% = 8.33\%$$

Figure 5 shows typical boost region waveforms. If  $V_{IN}$  approaches  $V_{OUT}$ , the buck-boost region is reached.

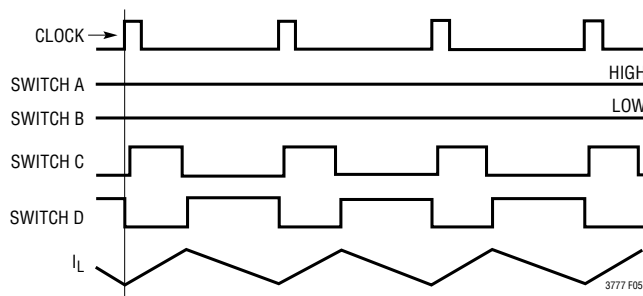


Figure 5. Boost Region ( $V_{IN} \ll V_{OUT}$ )

### Light Load Current Operation (MODE Pin)

The LTC3777 can be enabled to enter pulse-skipping mode or forced continuous conduction mode. To select forced continuous operation, tie the MODE pin to a DC voltage below 0.8V (e.g., SGND). To select pulse-skipping mode of operation, tie the MODE pin to V5.

## OPERATION

**Pulse-Skipping Mode:** When the LTC3777 enters pulse-skipping or discontinuous mode, in the boost region, synchronous switch D is held off whenever reverse current through switch A is detected. At very light loads, the current comparator,  $I_{CMP}$ , may remain tripped for several cycles and force switch C to stay off for the same number of cycles (i.e., skipping pulses). In the buck region, the inductor current is not allowed to reverse. Synchronous switch B is held off whenever reverse current on the inductor is detected. At very light loads, the current comparator,  $I_{CMP}$ , may remain untripped for several cycles, holding switch A off for the same number of cycles. Synchronous switch B also remains off for the skipped cycles. In the buck-boost region, the controller operates alternatively in boost and buck regions in one clock cycle, as in continuous operation. A small amount of reverse current is allowed, to minimize ripple. For the same reason, a narrow band of continuous buck and boost operation is allowed on the high and low line ends of the buck-boost region.

**Forced Continuous Mode:** The forced continuous mode allows the inductor current to reverse directions without any switches being forced “off” to prevent this from happening. At very light load currents the inductor current will swing positive and negative as the appropriate average current is delivered to the output. During soft-start, if the SS pin is lower than  $V_{FB}$ , the part will be forced into discontinuous mode to prevent pulling current from the output to the input. After SS voltage crosses  $V_{FB}$  or 1.32V, whichever is lower, forced continuous mode will be enabled.

### Output Overvoltage

If the output voltage is higher than the value commanded by the  $V_{FB}$  resistor divider, the LTC3777 will respond according to the mode and region of operation. In continuous conduction mode, the LTC3777 will sink current into the input. If the input supply is capable of sinking current, the LTC3777 will allow up to about  $80\text{mV}/R_{SENSE}$  to be sunk into the input. In pulse-skipping mode and in the buck or boost regions, switching will stop and the output will be allowed to remain high. In pulse-skipping mode, and in the buck-boost region as well as the narrow band of continuous boost operation that adjoins

it, current sunk into the input through switch A is limited to approximately  $40\text{mV}/R_{DS(ON)}$  of switch A. If this level is reached, switching will stop and the output will rise. In pulse-skipping mode, and in the narrow continuous buck region that adjoins the buck/boost region, current sunk into the input through  $R_{SENSE}$  is limited to approximately  $40\text{mV}/R_{SENSE}$ .

### Voltage Regulation Loop

The LTC3777 provides a constant-voltage regulation loop, for regulating the output voltage. A resistor divider between  $V_{OUT}$ ,  $V_{FB}$  and GND senses the output voltage. As with traditional voltage regulators, when  $V_{FB}$  rises near or above the reference voltage of EA (1.2V typical, see Block Diagram), the ITH voltage is reduced to command the amount of current that keeps  $V_{OUT}$  regulated to the desired voltage.

### Constant-Current Regulation ( $I_{AVGSNSP}$ and $I_{AVGSNSN}$ Pins)

The LTC3777 provides a constant-current regulation loop for either input or output current. A sensing resistor close to the input or output capacitor will sense the input or output current. When the current exceeds the programmed current limit, the voltage on the ITH pin will be pulled down to maintain the desired maximum input or output current. The input current limit function prevents overloading the DC input source, while the output current limit provides a building block for battery charger or LED driver applications. It can also serve as an extra current limit protection for a constant-voltage regulation application. The input or output current limit function has an operating voltage range of GND to the absolute maximum  $V_{IN}$  or  $V_{OUT}$ , respectively.

### Frequency Selection and Phase-Locked Loop (FREQ and PLLIN Pins)

The selection of switching frequency is a trade-off between efficiency and component size. Low frequency operation increases efficiency by reducing MOSFET switching losses, but requires larger inductance and/or capacitance to maintain low output ripple voltage. The switching frequency of the LTC3777's controllers can be selected using the FREQ pin. If the SYNC pin is not being

3777f

## OPERATION

driven by an external clock source, the FREQ pin can be used to program the controller's operating frequency from 50kHz to 600kHz.

Switching frequency is determined by the voltage on the FREQ pin. Since there is a precision 20 $\mu$ A current flowing out of the FREQ pin, the user can program the controller's switching frequency with a single resistor to SGND. Figure 9 in the [Applications Information](#) section shows the relationship between the FREQ pin resistor value and the switching frequency.

A phase-locked loop (PLL) is integrated on the LTC3777 to synchronize the internal oscillator to an external clock source driving the PLLIN pin. While LTC3777 is being synchronized to an external clock source, depending on the voltage of the MODE pin, it can be enabled to enter pulse-skipping mode or forced continuous conduction mode. The PLL filter network is integrated inside the LTC3777.

The PLL is capable of locking to any frequency within the range of 50kHz to 600kHz. The frequency setting resistor should always be present to set the controller's initial switching frequency before locking to the external clock.

### Power Good (PGOOD) Pins

The PGOOD pin is connected to the open drain of an internal N-channel MOSFET. When  $V_{FB}$  is not within  $\pm 10\%$  of the 1.2V reference voltage, the PGOOD pin is pulled low. The PGOOD pin is also pulled low when RUN is below 1.1V or when the LTC3777 is in the soft-start phase. There is an internal 125 $\mu$ s power good or bad mask when  $V_{FB}$  goes in or out of the  $\pm 10\%$  window. The PGOOD pin is allowed to be pulled up by an external resistor to V5 or an external source of up to 6V.

### Short-Circuit Protection, Current Limit and Current Limit Foldback

The maximum current threshold of the controller is limited by a voltage clamp on the ITH pin. In every boost cycle, the sensed maximum peak voltage is limited to 140mV. In every buck cycle, the sensed maximum valley voltage is limited to 90mV. In the buck-boost region, only peak sensed voltage is limited by the same threshold as in the boost region.

The LTC3777 includes current foldback to help limit load current when the output is shorted to ground. If the output falls below 50% of its nominal output level, then the maximum sense voltage is progressively lowered from its maximum value to one-third of the maximum value. Foldback current limiting is disabled during the soft-start. Under short-circuit conditions, the LTC3777 will limit the current by operating as a buck with very low duty cycles, and by skipping cycles. In this situation, synchronous switch B will dissipate most of the power (but less than in normal operation).

### Thermal Shutdown

The LTC3777 has a temperature sensor integrated on the IC, to sense the die temperature near the gate driver circuits. When the die temperature exceeds 175°C, all switching actions stop, the top GATE pins are held low, and the bottom GATE pins are held high, and  $V_{OUT}$  is disconnected from  $V_{IN}$ . At the same time, the SS pin is pulled low by an internal MOSFET. When the temperature drops 10°C below the trip threshold, the part goes through a SS reset cycle and normal operation resumes.

### Input Undervoltage and Overvoltage Lockout

The LTC3777 implements a protection feature that inhibits switching when the input voltage rises above a programmable operating range. By using a resistor divider from the input supply to ground, the RUN and VINO pins serve as a precise input supply voltage monitor. Switching is disabled when either the RUN pin falls below 1.1V or the VINO pin rises above 1.28V, which can be configured to limit switching to a specific range of input supply voltage.

When switching is disabled, the LTC3777 can safely sustain input voltages on the RUN pin up to the absolute maximum rating of 150V. Input supply undervoltage or overvoltage events trigger a soft-start reset, which results in a graceful recovery from an input supply transient.

### Integrated Switching Bias Supply

The switching bias supply is a synchronous step-down DC/DC regulator with internal power switches that uses Burst Mode<sup>®</sup> control, combining low quiescent current with high switching frequency, which results in high

## OPERATION

efficiency across a wide range of load currents. Burst Mode operation functions by using short “burst” cycles to switch the inductor current through the internal power MOSFETs, followed by a sleep cycle where the power switches are off and the load current is supplied by the output capacitor. During the sleep cycle, it draws only 12 $\mu$ A of supply current. At light loads, the burst cycles are a small percentage of the total cycle time which minimizes the average supply current, greatly improving efficiency.

If the voltage on the BRUN pin is less than 0.7V, the switching bias supply enters a shutdown mode in which all internal circuitry is disabled, reducing the DC supply current to 1.4 $\mu$ A. When the voltage on the BRUN pin exceeds 1.21V, normal operation of the main control loop is enabled. The BRUN pin comparator has 110mV of internal hysteresis, and therefore must fall below 1.1V to disable the main control loop.

An internal 1ms soft-start function limits the ramp rate of the output voltage on start-up to prevent excessive input supply droop. The internal soft-start function is reset on start-up and after an undervoltage or overvoltage event on the input supply.

The peak current comparator has a maximum current limit of at least 170mA, which guarantees a maximum average current of 85mA. Shorting the BI<sub>SET</sub> pin to ground programs the current limit to 20mA, and leaving it floating sets the current limit to the maximum value of 200mA.

Input undervoltage and overvoltage lockout protection features will inhibit switching when the input voltage is not within a programmable operating range. By use of a resistive divider from the input supply to ground, the BRUN and BOV pins serve as a precise input supply voltage monitor. Switching is disabled when either the BRUN pin falls below 1.1V or the BOV pin rises above 1.21V, which can be configured to limit switching to a specific range of input supply voltage. Furthermore, if the input voltage falls below 3.5V typical (3.8V maximum), an internal undervoltage detector disables switching.

Input supply undervoltage or overvoltage events trigger a soft-start reset, which results in a graceful recovery from an input supply transient.

## APPLICATIONS INFORMATION

The [Typical Application](#) on the first page is a basic LTC3777 application circuit. External component selection is driven by the load requirement, and begins with the selection of R<sub>SENSE</sub> and the inductor value. Next, the power MOSFETs are selected. Finally, C<sub>IN</sub> and C<sub>OUT</sub> are selected. This circuit can be configured for operation up to an input voltage of 150V.

### Inductor Current Sensing and Slope Compensation

The LTC3777 operates using inductor current mode control. The LTC3777 measures the peak of the inductor current waveform in the boost region and the valley of the inductor current waveform in the buck region. The inductor current is sensed across the R<sub>SENSE</sub> resistor with pins SENSEP and SENSEN. During any given cycle, the peak (boost region) or valley (buck region) of the inductor current is controlled by the ITH pin voltage.

Slope compensation provides stability in constant frequency architectures by preventing subharmonic oscillations at high duty cycles in boost operation and at low duty cycles in buck operation. This is accomplished internally by adding a compensating ramp to the inductor current signal at duty cycles in excess of 40% in the boost region, or subtracting a ramp from the inductor current signal at lower than 40% duty cycles in the buck region. Normally, this results in a reduction of maximum inductor peak current for duty cycles >40% in the boost region, or an increase of maximum inductor current for duty cycles <40% in the buck region. However, the LTC3777 uses a scheme that counteracts this compensating ramp, which allows the maximum inductor current to remain unaffected throughout all duty cycles.

## APPLICATIONS INFORMATION

### R<sub>SENSE</sub> Selection and Maximum Output Current

The R<sub>SENSE</sub> resistance must be chosen properly to achieve the desired amount of output current. Too much resistance can limit the output current below the application requirements. Start by determining the maximum allowed R<sub>SENSE</sub> resistance in the boost region, R<sub>SENSE(MAX,BOOST)</sub>. Follow this by finding the maximum allowed R<sub>SENSE</sub> resistance in the buck region, R<sub>SENSE(MAX,BUCK)</sub>. The selected R<sub>SENSE</sub> resistance must be smaller than both. Figure 6 shows how I<sub>LOAD(MAX)</sub> • R<sub>SENSE</sub> varies with input and output voltage.

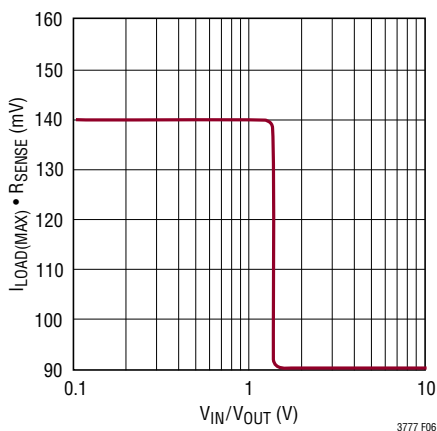


Figure 6. Load Current vs V<sub>IN</sub>/V<sub>OUT</sub>

**Boost Region:** In the boost region, the maximum output current capability is the least when V<sub>IN</sub> is at its minimum and V<sub>OUT</sub> is at its maximum. Therefore R<sub>SENSE</sub> must be chosen to meet the output current requirements under these conditions.

Start by finding the boost region duty cycle when V<sub>IN</sub> is minimum and V<sub>OUT</sub> is maximum using:

$$DC_{(MAX,C,BOOST)} \equiv \left( 1 - \frac{V_{IN(MIN)}}{V_{OUT(MAX)}} \right) \cdot 100\%$$

For example, an application with a V<sub>IN</sub> range of 12V to 48V and V<sub>OUT</sub> set to 36V will have:

$$DC_{(MAX,C,BOOST)} \equiv \left( 1 - \frac{12V}{36V} \right) \cdot 100\% = 67\%$$

Next, the inductor ripple current in the boost region must be determined. If the main inductor L is not known, the maximum ripple current  $\Delta I_{L(MAX,BOOST)}$  can be estimated by choosing  $\Delta I_{L(MAX,BOOST)}$  to be 30% to 50% of the maximum inductor current in the boost region as follows:

$$\Delta I_{L(MAX,BOOST)} \equiv \frac{V_{OUT(MAX)} \cdot I_{OUT(MAX,BOOST)}}{V_{IN(MIN)} \cdot \left( \frac{100\%}{\%Ripple} - 0.5 \right)} A$$

where:

I<sub>OUT(MAX,BOOST)</sub> is the maximum output load current required in the boost region

%Ripple is 30% to 50%

For example, using V<sub>OUT(MAX)</sub> = 36V, V<sub>IN(MIN)</sub> = 12V, I<sub>OUT(MAX,BOOST)</sub> = 2A and %Ripple = 40% we can estimate:

$$\Delta I_{L(MAX,BOOST)} \equiv \frac{36V \cdot 2A}{12V \cdot \left( \frac{100\%}{40\%} - 0.5 \right)} = 3A$$

Otherwise, if the inductor value is already known then  $\Delta I_{L(MAX,BOOST)}$  can be more accurately calculated as follows:

$$\Delta I_{L(MAX,BOOST)} = \frac{\left( \frac{DC_{(MAX,C,BOOST)}}{100\%} \right) \cdot V_{IN(MIN)}}{f \cdot L} A$$

where:

DC<sub>(MAX,C,BOOST)</sub> is the maximum duty cycle percentage in the boost region as calculated previously.

f is the switching frequency

L is the inductance of the main inductor

After the maximum ripple current is known, the maximum allowed R<sub>SENSE</sub> in the boost region can be calculated as follows:

$$R_{SENSE(MAX,BOOST)} = \frac{2 \cdot V_{RSENSE(MAX,BOOST,MAXDC)} \cdot V_{IN(MIN)}}{\left( 2 \cdot I_{OUT(MAX,BOOST)} \cdot V_{OUT(MIN)} \right) + \left( \Delta I_{L(MAX,BOOST)} \cdot V_{IN(MIN)} \right)} \Omega$$

## APPLICATIONS INFORMATION

where  $V_{RSENSE(MAX,BOOST,MAXDC)}$  is the maximum inductor current sense voltage as discussed in the previous section.

Using values from the previous examples:

$$R_{SENSE(MAX,BOOST)} = \frac{2 \cdot 140\text{mV} \cdot 12}{(2 \cdot 2\text{A} \cdot 36\text{V}) + (3\text{A} \cdot 12\text{V})} = 18.66\text{m}\Omega$$

**Buck Region:** The duty cycle for buck operation can be calculated using:

$$DC_{(MAX,B,BUCK)} \cong \left( 1 - \frac{V_{OUT(MIN)}}{V_{IN(MAX)}} \right) \cdot 100\%$$

Before calculating the maximum  $R_{SENSE}$  resistance, however, the inductor ripple current must be determined. If the main inductor  $L$  is not known, the ripple current  $\Delta I_{L(MIN,BUCK)}$  can be estimated by choosing  $\Delta I_{L(MIN,BUCK)}$  to be 10% of the maximum inductor current in the buck region as follows:

$$\Delta I_{L(MIN,BUCK)} \cong \left( \frac{100\%}{10\%} - 0.5 \right) \cdot I_{OUT(MAX,BUCK)} \text{ A}$$

where:

$I_{OUT(MAX,BUCK)}$  is the maximum output load current required in the buck region.

If the inductor value is already known then  $\Delta I_{L(MIN,BUCK)}$  can be calculated as follows:

$$\Delta I_{L(MIN,BUCK)} = \frac{\left( \frac{DC_{(MIN,B,BUCK)}}{100\%} \right) \cdot V_{OUT(MIN)}}{f \cdot L} \text{ A}$$

where:

$DC_{(MIN,B,BUCK)}$  is the minimum duty cycle percentage in the buck region as calculated previously.

$f$  is the switching frequency

$L$  is the inductance of the main inductor

After the inductor ripple current is known, the maximum allowed  $R_{SENSE}$  in the buck region can be calculated as follows:

$$R_{SENSE(MAX,BUCK)} = \frac{2 \cdot V_{RSENSE(MAX,BUCK,MINDC)}}{(2 \cdot I_{OUT(MAX,BUCK)}) - \Delta I_{L(MIN,BUCK)}} \Omega$$

### Programming Input/Output Current Limit

As shown in Figure 7 and Figure 8, input/output current sense resistor  $R_{SENSE2}$  should be placed between the bulk capacitor for  $V_{IN}$  or  $V_{OUT}$  and the decoupling capacitor. A lowpass filter formed by  $R_F$  and  $C_F$  is recommended to reduce the switching noise and stabilize the current loop. The input/output current limit is set internally to 50mV. If input/output current limit is not desired, the  $I_{AVGSNSP}$  and  $I_{AVGSNSN}$  pins should be shorted together to  $V_5$ .

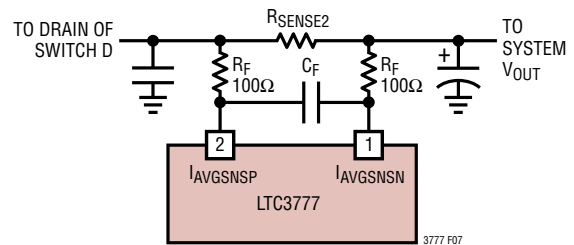


Figure 7. Programming Output Current Limit

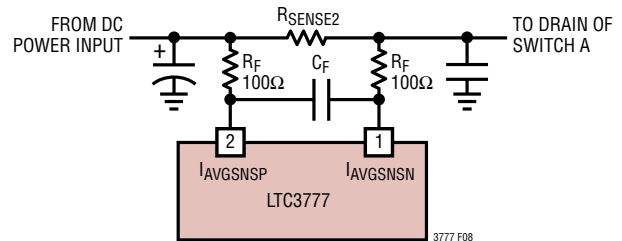


Figure 8. Programming Input Current Limit

With the typical 100Ω resistors shown here, the value of capacitor  $C_F$  should be 1μF to 4.7μF. The current loop's transfer function should approximate that of the voltage loop. Crossover frequency should be one-tenth the switching frequency, and gain should decrease by 20dB/decade. Similar current and voltage loop transfer functions will ensure overall system stability.

When the  $I_{AVGSNS}$  common mode voltage is above ~4V, the  $I_{AVGSNSN}$  pin sources 10μA. The  $I_{AVGSNSP}$  pin, however, sources 15μA, when a constant current is being regulated.

## APPLICATIONS INFORMATION

The error introduced by this mismatch can be offset to a first order by scaling the  $I_{AVGSNSP}$  and  $I_{AVGSNSN}$  resistors accordingly. For example, if the  $I_{AVGSNSP}$  branch has a  $100\Omega$  resistor, the  $1.50\text{mV}$  across it can be replicated in the  $I_{AVGSNSN}$  branch by using a  $150\Omega$  resistor.

When the  $I_{AVGSNS}$  common mode voltage falls below  $\sim 4\text{V}$ , the  $I_{AVGSNS}$  current decreases linearly; it reaches approximately  $-300\mu\text{A}$  at zero volts. The maximum current sinking can vary by 20% to 30% due to process variation. Ensure that  $I_{AVGSNS}$  common mode voltage never exceeds its absolute maximum of  $-10\text{V}$  below ground. Pay special attention to short-circuit conditions in high power applications.

### Phase-Locked Loop and Frequency Synchronization

The LTC3777 has a phase-locked loop (PLL) comprised of an internal voltage-controlled oscillator (VCO) and a phase detector. This allows the turn-on of the bottom MOSFET of the controller to be locked to the rising edge of an external clock signal applied to the PLLIN pin. The phase detector is an edge sensitive digital type that provides zero degrees phase shift between the external and internal oscillators. This type of phase detector does not exhibit false locking to harmonics of the external clock.

The output of the phase detector is a pair of complementary current sources that charge or discharge the internal filter network. There is a precision  $20\mu\text{A}$  of current flowing out of the FREQ pin. This allows a single resistor to SGND to set the switching frequency when no external clock is applied to the PLLIN pin. The internal switch between FREQ and the integrated PLL filter network is on, allowing the filter network to be pre-charged at the same voltage as the FREQ pin. The relationship between the voltage on the FREQ pin and operating frequency is shown in Figure 9 and specified in the [Electrical Characteristics](#) table. If an external clock is detected on the PLLIN pin, the internal switch previously mentioned will turn off and isolate the influence of the FREQ pin.

Note that the LTC3777 can only be synchronized to an external clock whose frequency is within range of the LTC3777's internal VCO. This is guaranteed to be between  $50\text{kHz}$  and  $600\text{kHz}$ . A simplified block diagram is shown in Figure 10.

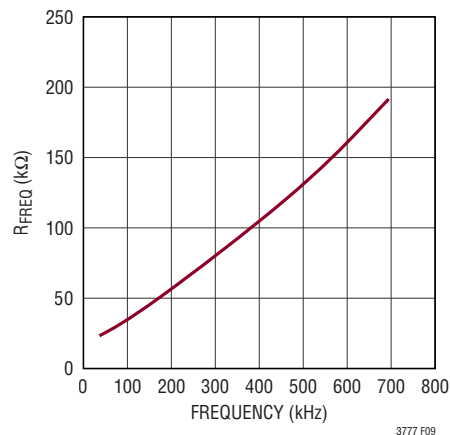


Figure 9. FREQ Pin Resistor Value vs Frequency

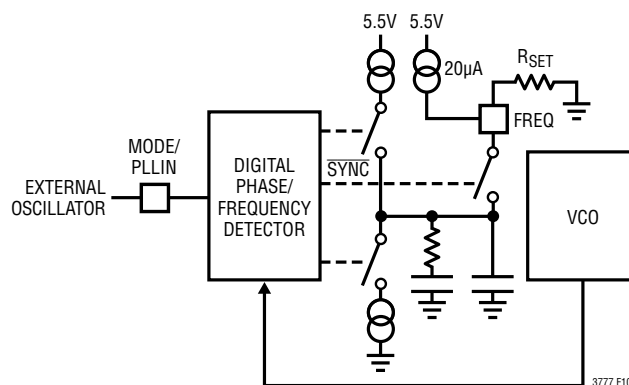


Figure 10. Phase-Locked Loop Block Diagram

If the external clock frequency is greater than the internal oscillator's frequency,  $f_{OSC}$ , then current is sourced continuously from the phase detector output, pulling up the filter network. When the external clock frequency is less than  $f_{OSC}$ , current is sunk continuously, pulling down the filter network. If the external and internal frequencies are the same but exhibit a phase difference, the current sources turn on for the amount of time corresponding to the phase difference. The voltage on the filter network is adjusted until the phase and frequency of the internal and external oscillators are identical. At the stable operating point, the phase detector output is high impedance and the filter capacitor holds the voltage.

Typically, the external clock (on the PLLIN pin) input high threshold is  $2\text{V}$ , while the input low threshold is  $1.2\text{V}$ .

## APPLICATIONS INFORMATION

The operating frequency of the LTC3777 can be approximated using the following formula:

$$R_{\text{FREQ}} = 0.000115(f_{\text{OSC}})^2 + 0.174(f_{\text{OSC}}) + 18.5$$

where  $f_{\text{OSC}}$  is in kHz and  $R_{\text{FREQ}}$  is in k $\Omega$ .

### Inductor Selection

The operating frequency and inductor selection are interrelated in that higher operating frequencies allow the use of smaller inductor and capacitor values. The inductor value has a direct effect on ripple current. The inductor current ripple  $\Delta I_L$  is typically set to 20% to 40% of the maximum inductor current in the boost region at  $V_{\text{IN(MIN)}}$ . For a given ripple the inductance terms in continuous mode are as follows:

$$L_{\text{BOOST}} > \frac{V_{\text{IN(MIN)}}^2 \cdot (V_{\text{OUT}} - V_{\text{IN(MIN)}}) \cdot 100}{f \cdot I_{\text{OUT(MAX)}} \cdot \% \text{Ripple} \cdot V_{\text{OUT}}^2} \text{H},$$

$$L_{\text{BUCK}} > \frac{V_{\text{OUT}} \cdot (V_{\text{IN(MAX)}} - V_{\text{OUT}}) \cdot 100}{f \cdot I_{\text{OUT(MAX)}} \cdot \% \text{Ripple} \cdot V_{\text{IN(MAX)}}} \text{H}$$

where:

$f$  is operating frequency, Hz

% Ripple is allowable inductor current ripple

$V_{\text{IN(MIN)}}$  is minimum input voltage, V

$V_{\text{IN(MAX)}}$  is maximum input voltage, V

$V_{\text{OUT}}$  is output voltage, V

$I_{\text{OUT(MAX)}}$  is maximum output load current, A

For high efficiency, choose an inductor with low core loss, such as ferrite. Also, the inductor should have low DC resistance to reduce the  $I^2R$  losses, and must be able to handle the peak inductor current without saturating. To minimize radiated noise, use a toroid, pot core or shielded bobbin inductor.

### Inductor Core Selection

Once the inductance value is determined, the type of inductor must be selected. Core loss is independent of core size for a fixed inductor value, but it is very dependent on inductance selected. As inductance increases, core

losses go down. Unfortunately, increased inductance requires more turns of wire and therefore copper losses will increase.

Ferrite designs have very low core loss and are preferred at high switching frequencies, so design goals can concentrate on copper loss and preventing saturation. Ferrite core material saturates “hard,” which means that inductance collapses abruptly when the peak design current is exceeded. This results in an abrupt increase in inductor ripple current and consequent output voltage ripple. Do not allow the core to saturate!

### $C_{\text{IN}}$ and $C_{\text{OUT}}$ Selection

In the boost region, input current is continuous. In the buck region, input current is discontinuous. In the buck region, the selection of input capacitor  $C_{\text{IN}}$  is driven by the need to filter the input square wave current. Use a low ESR capacitor sized to handle the maximum RMS current. For buck operation, the input RMS current is given by:

$$I_{\text{RMS}} \approx I_{\text{OUT(MAX)}} \cdot \frac{V_{\text{OUT}}}{V_{\text{IN}}} \cdot \sqrt{\frac{V_{\text{IN}}}{V_{\text{OUT}}} - 1}$$

This formula has a maximum at  $V_{\text{IN}} = 2V_{\text{OUT}}$ , where  $I_{\text{RMS}} = I_{\text{OUT(MAX)}}/2$ . This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief. Note that ripple current ratings from capacitor manufacturers are often based on only 2000 hours of life which makes it advisable to derate the capacitor.

In the boost region, the discontinuous current shifts from the input to the output, so  $C_{\text{OUT}}$  must be capable of reducing the output voltage ripple. The effects of ESR (equivalent series resistance) and the bulk capacitance must be considered when choosing the right capacitor for a given output ripple voltage. The steady ripple due to charging and discharging the bulk capacitance is given by:

$$\Delta V_{\text{RIPPLE(BOOST,CAP)}} = \frac{I_{\text{OUT(MAX)}} \cdot (V_{\text{OUT}} - V_{\text{IN(MIN)}})}{C_{\text{OUT}} \cdot V_{\text{OUT}} \cdot f} \text{V}$$

where  $C_{\text{OUT}}$  is the output filter capacitor.



## APPLICATIONS INFORMATION

The steady ripple due to the voltage drop across the ESR is given by:

$$\Delta V_{(\text{BOOST,ESR})} = I_{\text{OUT(MAX,BOOST)}} \cdot \text{ESR}$$

In buck mode,  $V_{\text{OUT}}$  ripple is given by:

$$\Delta V_{\text{OUT}} \leq \Delta I_L \left( \text{ESR} + \frac{1}{8 \cdot f \cdot C_{\text{OUT}}} \right)$$

Multiple capacitors placed in parallel may be needed to meet the ESR and RMS current handling requirements. Aluminum electrolytic and ceramic capacitors are available in surface mount packages. Ceramic capacitors have excellent low ESR characteristics but can have a high voltage coefficient. Bulk capacitors are now available with low ESR and high ripple current ratings, such as OSCON and aluminum electrolytics with hybrid conductive polymers.

### Power MOSFET Selection and Efficiency Considerations

The LTC3777 requires four external N-channel power MOSFETs, two for the top switches (switches A and D, shown in Figure 1) and two for the bottom switches (switches B and C, shown in Figure 1). Important parameters for the power MOSFETs are the breakdown voltage  $V_{\text{BR,DSS}}$ , threshold voltage  $V_{\text{GS,TH}}$ , on-resistance  $R_{\text{DS(ON)}}$ , reverse transfer capacitance  $C_{\text{RSS}}$  and maximum current  $I_{\text{DS(MAX)}}$ .

The peak-to-peak drive levels are set by the  $\text{DRV}_{\text{CC}}$  voltage. This voltage can range from 6V to 10V depending on the  $\text{DRVSET}$  pin setting. Therefore, both logic-level and standard-level threshold MOSFETs can be used in most applications, depending on the programmed  $\text{DRV}_{\text{CC}}$  voltage. Pay close attention to the  $\text{BV}_{\text{DSS}}$  specification for the MOSFETs as well.

The LTC3777's ability to adjust the gate drive level between 6V to 10V allows an application circuit to be precisely optimized for efficiency. When adjusting the gate drive level, the final arbiter is the total input current for the regulator. If a change is made and the input current decreases, then the efficiency has improved. If there is no change in input current, then there is no change in efficiency.

In order to select the power MOSFETs, the power dissipated by the device must be known. For switch A, the maximum power dissipation happens in the boost region, when it remains on all the time. Its maximum power dissipation at maximum output current is given by:

$$P_{\text{A,BOOST}} = \left( \frac{V_{\text{OUT}}}{V_{\text{IN}}} \cdot I_{\text{OUT(MAX)}} \right)^2 \cdot \rho_{\tau} \cdot R_{\text{DS(ON)}}$$

where  $\rho_{\tau}$  is a normalization factor (unity at 25°C) accounting for the significant variation in on-resistance with temperature, typically about 0.4%/°C, as shown in Figure 11. For a maximum junction temperature of 125°C, using a value  $\rho_{\tau} = 1.5$  is reasonable.

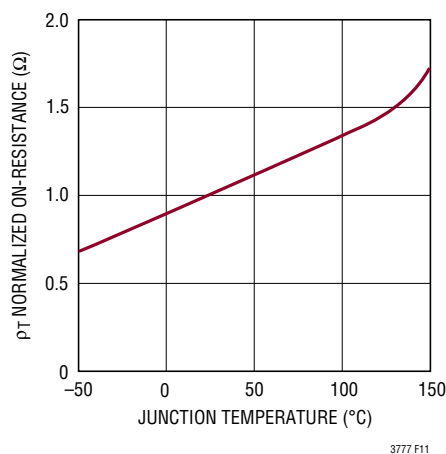


Figure 11. Normalized  $R_{\text{DS(ON)}}$  vs Temperature

Switch B operates in the buck region as the synchronous rectifier. Its power dissipation at maximum output current is given by:

$$P_{\text{B,BUCK}} = \frac{V_{\text{IN}} - V_{\text{OUT}}}{V_{\text{IN}}} \cdot I_{\text{OUT(MAX)}}^2 \cdot \rho_{\tau} \cdot R_{\text{DS(ON)}}$$

Switch C operates in the boost region as the control switch. Its power dissipation at maximum current is given by:

$$P_{\text{C,BOOST}} = \frac{(V_{\text{OUT}} - V_{\text{IN}}) V_{\text{OUT}}}{V_{\text{IN}}^2} \cdot I_{\text{OUT(MAX)}}^2 \cdot \rho_{\tau} \cdot R_{\text{DS(ON)}} + k \cdot V_{\text{OUT}}^3 \cdot \frac{I_{\text{OUT(MAX)}}}{V_{\text{IN}}} \cdot C_{\text{RSS}} \cdot f$$

## APPLICATIONS INFORMATION

where  $C_{RSS}$  is usually specified by the MOSFET manufacturers. The constant  $k$ , which accounts for the loss caused by reverse recovery current, is inversely proportional to the gate drive current and has an empirical value of 1.7.

For switch D, the maximum power dissipation happens in the boost region, when its duty cycle is higher than 50%. Its maximum power dissipation at maximum output current is given by:

$$P_{D,BOOST} = \frac{V_{IN}}{V_{OUT}} \cdot \left( \frac{V_{OUT}}{V_{IN}} \cdot I_{OUT(MAX)} \right)^2 \cdot \rho_{\tau} \cdot R_{DS(ON)}$$

For the same output voltage and current, switch A has the highest power dissipation and switch B has the lowest power dissipation unless a short occurs at the output.

From a known power dissipated in the power MOSFET, its junction temperature can be obtained using the following formula:

$$T_J = T_A + P \cdot R_{TH(JA)}$$

The  $R_{TH(JA)}$  to be used in the equation normally includes the  $R_{TH(JC)}$  for the device plus the thermal resistance from the case to the ambient temperature ( $R_{TH(JC)}$ ). This value of  $T_J$  can then be compared to the original, assumed value used in the iterative calculation process.

### Schottky Diode (D1, D2) Selection

The Schottky diodes, D1 and D2, shown in the [Block Diagram](#), conduct during the dead time between the conduction of the power MOSFET switches. They are intended to prevent the body diode of synchronous switches B and D from turning on and storing charge during the dead time. In particular, D2 significantly reduces reverse recovery current between switch D turn-off and switch C turn-on, which improves converter efficiency and reduces switch C voltage stress. In order for the diode to be effective, the inductance between it and the synchronous switch must be as small as possible, mandating that these components be placed adjacently.

### Setting Output Voltage

The LTC3777 output voltage is set by two external feedback resistive dividers carefully placed across the output, as shown in Figure 12. The regulated output voltage is determined by:

$$V_{OUT} = 1.2V \cdot (1 + R_B/R_A)$$

To improve the frequency response, a feed forward capacitor,  $C_{FF}$ , may be used. Great care should be taken to route the  $V_{FB}$  line away from noise sources, such as the inductor or the SW line.

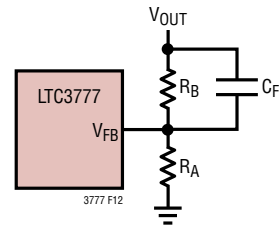


Figure 12. Setting Output Voltage

### RUN Pin and Overvoltage/Undervoltage Lockout

The LTC3777 is enabled using the RUN pin. It has a rising threshold of 1.2V with 100mV of hysteresis. Pulling the RUN pin below 1.1V shuts down the main control loop for the controller and most internal circuits, including the  $DRV_{CC}$  and V5 LDOs. In this state the LTC3777 draws only 40 $\mu$ A of quiescent current. Releasing the RUN pin allows an internal 2.5 $\mu$ A current to pull-up the pin and enable the controller. The RUN comparator itself has about 100mV of hysteresis. When the voltage on the RUN pin exceeds 1.2V, the current sourced into the RUN pin is switched from 2.5 $\mu$ A to 6.5 $\mu$ A current. The user can therefore program both the rising threshold and the amount of hysteresis using an external resistive divider.

The RUN pin is high impedance above 3V and must be externally pulled up/down or driven directly by logic, as shown in Figure 13. The RUN pin can tolerate up to 150V (absolute maximum), so it can be conveniently tied to  $V_{IN}$  in always-on applications where the controller is enabled continuously and never shut down.

## APPLICATIONS INFORMATION

The RUN and VINOV pins can alternatively be configured as undervoltage (UVLO) and overvoltage (OVLO) lockouts on the  $V_{IN}$  supply with a resistor divider from  $V_{IN}$  to ground. A simple resistor divider can be used as shown in Figure 14 to meet specific  $V_{IN}$  voltage requirements. One can program additional hysteresis for the RUN comparator by adjusting the values of the resistive divider.

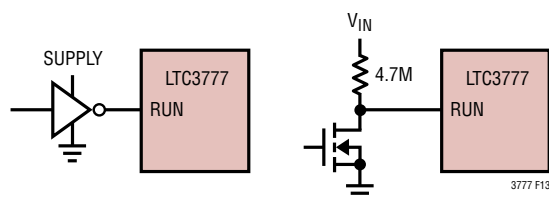


Figure 13. RUN Pin Interface to Logic

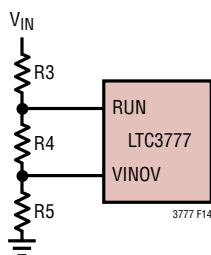


Figure 14. Adjustable UV and OV Lockout

The current that flows through the R3-R4-R5 divider will directly add to the shutdown and active current of the LTC3777, and care should be taken to minimize the impact of this current on the overall efficiency of the application circuit. Resistor values in the megohm range may be required to keep the impact on quiescent shutdown current low. To pick resistor values, the sum total of  $R3 + R4 + R5$  ( $R_{TOTAL}$ ) should be chosen first based on the allowable DC current that can be drawn from  $V_{IN}$ .

The individual values of R3, R4 and R5 can then be calculated from the following equations:

$$R5 = R_{TOTAL} \cdot \left( \frac{1.2V}{\text{Rising } V_{IN} \text{ OVLO Threshold}} \right)$$

$$R4 = R_{TOTAL} \cdot \left( \frac{1.2V}{\text{Rising } V_{IN} \text{ UVLO Threshold}} \right) - R5$$

$$R3 = R_{TOTAL} - R4 - R5$$

For applications that do not need a precise external OVLO, the VINOV pin should be tied directly to ground. The RUN pin in this type of application can be used as an external UVLO using the following equations with  $R5 = 0\Omega$ .

$$V_{IN(ON)} = 1.2V \left( 1 + \frac{R3}{R4} \right) - 2.5\mu \cdot R3$$

$$V_{IN(OFF)} = 1.1V \left( 1 + \frac{R3}{R4} \right) - 6.5\mu \cdot R3$$

Similarly, for applications that do not require a precise UVLO, the RUN pin can be tied to  $V_{IN}$ . In this configuration, the UVLO threshold is limited to the internal  $V_{IN}$  UVLO thresholds as shown in the [Electrical Characteristics](#) table. The resistor values for the OVLO can be computed using the previous equations with  $R3 = 0\Omega$ .

Be aware that the VINOV pin cannot be allowed to exceed its absolute maximum rating of 6V. To keep the voltage on the VINOV pin from exceeding 6V, the following relation should be satisfied:

$$V_{IN(MAX)} \cdot \left( \frac{R5}{R3 + R4 + R5} \right) < 6V$$

### Soft-Start

The start-up of  $V_{OUT}$  is controlled by the voltage on the SS pin. If its RUN pin voltage is below 1.1V the controller is in the shutdown state; its SS pin is actively pulled to ground in this shutdown state. If the RUN pin voltage is above 1.2V, the controller powers up. A soft-start current of  $5\mu A$  then starts to charge the SS soft-start capacitor. Note that soft-start is achieved not by limiting the maximum output current of the controller but by controlling the output ramp voltage according to the ramp rate on the SS pin. When the voltage on the SS pin is less than the internal 1.2V reference, the LTC3777 regulates the  $V_{FB}$  pin voltage to the voltage on the SS pin instead of the internal reference. Current foldback is disabled during this phase. The soft-start range is defined to be the voltage range from 0V to 1.2V on the SS pin. The total soft-start time can be calculated as:

$$t_{SS} = C_{SS} \cdot \left( \frac{1.2V}{5\mu A} \right)$$

## APPLICATIONS INFORMATION

### DRV<sub>CC</sub> Regulator

In addition to the switching bias supply, the LTC3777 features two separate low dropout linear regulators (LDO) that can supply power at the DRV<sub>CC</sub> pin. The internal V<sub>IN</sub> LDO uses an internal P-channel pass device between the V<sub>IN</sub> and DRV<sub>CC</sub> pins. The internal EXT<sub>V</sub><sub>CC</sub> LDO uses an internal P-channel pass device between the EXT<sub>V</sub><sub>CC</sub> and DRV<sub>CC</sub> pins.

The DRV<sub>CC</sub> supply is regulated between 6V to 10V, depending on the DRVSET pin setting. The internal V<sub>IN</sub> and EXT<sub>V</sub><sub>CC</sub> LDOs can supply a peak current of at least 50mA. The DRV<sub>CC</sub> pin must be bypassed to ground with a minimum of 4.7μF ceramic capacitor. Good bypassing is needed to supply the high transient currents required by the MOSFET gate drivers. The DRVSET pin programs the DRV<sub>CC</sub> supply voltage and selects the appropriate EXT<sub>V</sub><sub>CC</sub> switchover threshold voltages as shown in the [Electrical Characteristics](#) table. The DRVSET pin has five logic level states. When DRVSET is either grounded, floated or tied to V<sub>5</sub>, the typical value for the DRV<sub>CC</sub> voltage will be 6V, 8V and 10V respectively. Use the 10V setting with careful PCB layout. This is because any overshoot between BOOST and SW would exceed the absolute maximum voltage of 11V for the floating driver. Set DRVSET to one-fourth of V<sub>5</sub> and three-fourths of V<sub>5</sub> for 7V and 9V DRV<sub>CC</sub> voltages. Please note that the DRVSET pin has an internal 200k pull-down to SGND and a 200k pull-up to V<sub>5</sub>. The EXT<sub>V</sub><sub>CC</sub> turn on threshold is the selected DRV<sub>CC</sub> regulation voltage minus 500mV. The turn off threshold is 500mV below the turn on threshold.

High input voltage applications in which large MOSFETs are being driven at high frequencies may cause the maximum junction temperature rating for the LTC3777 to be exceeded. The DRV<sub>CC</sub> current, which is dominated by the gate charge current, may be supplied by the V<sub>IN</sub> LDO, or the EXT<sub>V</sub><sub>CC</sub> LDO. When the voltage on the EXT<sub>V</sub><sub>CC</sub> pin is less than its switchover threshold (as determined by the DRVSET pin), the V<sub>IN</sub> LDO is enabled. Power dissipation in this case is highest and is equal to V<sub>IN</sub> • I<sub>DRVCC</sub>. This power is dissipated inside the IC. The gate charge current is dependent on operating frequency as discussed in the [Efficiency Considerations](#) section.

The junction temperature can be estimated by using the equations given in Note 2 of the [Electrical Characteristics](#) table. For example, if DRV<sub>CC</sub> is set to 6V, the DRV<sub>CC</sub> current is limited to less than 38mA from a 40V supply when not using the EXT<sub>V</sub><sub>CC</sub> LDO at a 70°C ambient temperature:

$$T_J = 70^\circ\text{C} + (38\text{mA})(40\text{V})(36^\circ\text{C}/\text{W}) = 125^\circ\text{C}$$

To prevent the maximum junction temperature from being exceeded, the V<sub>IN</sub> supply current must be checked while operating in forced continuous mode (MODE = SGND) at maximum V<sub>IN</sub>.

When the voltage applied to EXT<sub>V</sub><sub>CC</sub> rises above its switchover threshold, the V<sub>IN</sub> LDO is turned off and the EXT<sub>V</sub><sub>CC</sub> LDO is enabled. The EXT<sub>V</sub><sub>CC</sub> LDO remains on as long as the voltage applied to EXT<sub>V</sub><sub>CC</sub> remains above the switchover threshold minus the comparator hysteresis. The EXT<sub>V</sub><sub>CC</sub> LDO attempts to regulate the DRV<sub>CC</sub> voltage to the voltage as programmed by the DRVSET pin, so while EXT<sub>V</sub><sub>CC</sub> is less than this voltage, the LDO is in dropout and the DRV<sub>CC</sub> voltage is approximately equal to EXT<sub>V</sub><sub>CC</sub>. When EXT<sub>V</sub><sub>CC</sub> is greater than the programmed voltage, up to an absolute maximum of 36V, DRV<sub>CC</sub> is regulated to the programmed voltage.

Using the EXT<sub>V</sub><sub>CC</sub> LDO allows the MOSFET driver and control power to be derived from the LTC3777's switching regulator output (5.7V ≤ V<sub>OUT</sub> ≤ 36V) during normal operation and from the V<sub>IN</sub> LDO when the output is out of regulation (e.g., start-up, short-circuit).

Significant efficiency and thermal gains can be realized by powering DRV<sub>CC</sub> from the output, since the V<sub>IN</sub> current resulting from the driver and control currents will be scaled by a factor of (Duty Cycle)/(Switcher Efficiency).

For 5.5V to 36V regulator outputs, this means connecting the EXT<sub>V</sub><sub>CC</sub> pin directly to V<sub>OUT</sub>. Tying the EXT<sub>V</sub><sub>CC</sub> pin to a 12V supply reduces the junction temperature in the previous example from 125°C to:

$$T_J = 70^\circ\text{C} + 38\text{mA} \cdot (12\text{V})(36^\circ\text{C}/\text{W}) = 86^\circ\text{C}$$

While using the EXT<sub>V</sub><sub>CC</sub> LDO there is an V<sub>IN</sub> under voltage detection circuit that disables the EXT<sub>V</sub><sub>CC</sub> LDO if the V<sub>IN</sub> voltage is less than the DRV<sub>CC</sub> voltage that is set by the DRVSET pin.

## APPLICATIONS INFORMATION

For applications where the minimum  $V_{IN}$  voltage of LTC3777 needs to be less than 4.5V, the  $EXTV_{CC}$  pin can be used to power the  $V_{IN}$  of LTC3777. The  $V_{IN}$  under voltage detection circuit is disabled when  $DRVSET$  is set to three-fourths of  $V_5$ , for 9V  $DRV_{CC}$  voltage. Under this condition the  $DRV_{CC}$  voltage can be higher than the  $V_{IN}$  of LTC3777 and an external blocking diode should be connected from the  $V_{IN}$  pin of LTC3777 to the external  $V_{IN}$  supply, to avoid back feeding the  $V_{IN}$  supply.

The following list summarizes the four possible connections for  $EXTV_{CC}$ :

1.  $EXTV_{CC}$  grounded. This will cause  $DRV_{CC}$  to be powered from the internal  $V_{IN}$  LDO resulting in an efficiency penalty of up to 10% at high input voltages.
2.  $EXTV_{CC}$  connected directly to the regulator output. This is the normal connection for a 5.5V to 36V regulator and provides the highest efficiency.
3.  $EXTV_{CC}$  connected to  $BV_{OUT}$  the integrated switching bias supply output.

### V5 Regulator

An additional P-channel LDO supplies power at the  $V_5$  pin from the  $DRV_{CC}$  pin. Whereas  $DRV_{CC}$  powers the gate drivers,  $V_5$  powers much of the LTC3777's internal circuitry. The  $V_5$  LDO regulates the voltage at the  $V_5$  pin to 5.5V when  $DRV_{CC}$  is at least 6V. The LDO can supply a peak current of 20mA and must be bypassed to ground with a minimum of 4.7 $\mu$ F ceramic capacitor or low ESR electrolytic capacitor. No matter what type of bulk capacitor is used, an additional 0.1 $\mu$ F ceramic capacitor placed directly adjacent to the  $V_5$  and  $SGND$  pins is highly recommended.  $V_5$  is also used as a pull-up to bias other pins, such as  $MODE$ ,  $DRVSET$  and  $SS$ .

### Integrated Switching Bias Supply

The integrated switching bias is a 150V high efficiency step-down regulator with internal high side and synchronous power switches that can supply up to 85mA load current. The 150V switching bias draws only 12 $\mu$ A typical DC supply current while maintaining a regulated output voltage at no load. Using the integrated bias for high  $V_{IN}$  application increases the overall efficiency of the system, and reduces power dissipation.

The switching bias supply of LTC3777 can be used for the following purposes:

1. If the output voltage of the buck-boost controller is higher than 36V, which exceeds the absolute maximum voltage rating of the  $EXTV_{CC}$  pin, then the integrated switching bias supply can be used to provide a 12V bias to power the buck-boost controller.
2. It can also be used as a standalone bias to power other supply rails in the system.

For most applications, the design process to configure the switching bias supply is simple, summarized as follows:

1. In Table 1 find the row that has the desired input voltage and output voltage.
2. Apply the recommended  $C_{IN}$ ,  $C_{OUT}$ , L, R1 and R2.
3. Connect the  $BV_{OUT}$  to the  $EXTV_{CC}$  pin to bias the buck-boost controller.

The output voltage is set by an external resistive divider according to the following equation:

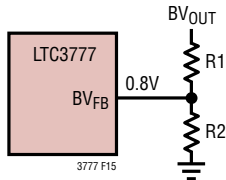
$$BV_{OUT} = 0.8V \cdot \left( 1 + \frac{R1}{R2} \right)$$

**Table 1. Switching Bias Supply Recommended Component Values and Configuration**

$BV_{IN}$	$BV_{OUT}$	$C_{IN}$	$C_{OUT}$	L	R1	R2
12V to 150V	12V	1 $\mu$ F TDK C5750X7R2E105K	2 $\times$ 22 $\mu$ F AVX 12103D226KAT2A	220 $\mu$ H SUMIDA CDRH105RNP-221NC	715k	51.1k
5V to 150V	5V	1 $\mu$ F TDK C5750X7R2E105K	10 $\mu$ F TDK C3216X7R1C106M	1000 $\mu$ H TDK SLF12555T-102MR34	422k	80.6k
4V to 150V	3.3V	1 $\mu$ F TDK C5750X7R2E105K	22 $\mu$ F AVX 12103D226KAT2A	150 $\mu$ H Coilcraft LPS6235-154ML	309k	97.6k

## APPLICATIONS INFORMATION

The resistive divider allows the  $BV_{FB}$  pin to sense a fraction of the output voltage as shown in Figure 15. The output voltage can range from 0.8V to  $V_{IN}$ . Be careful to keep the divider resistors very close to the  $BV_{FB}$  pin to minimize noise pick-up on the sensitive  $BV_{FB}$  trace.

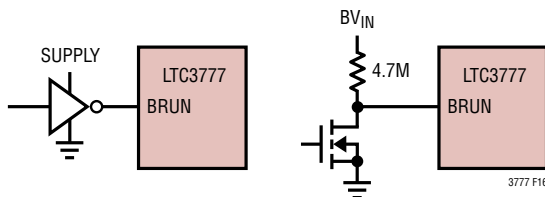


**Figure 15. Setting the Switching Bias Supply Output Voltage**

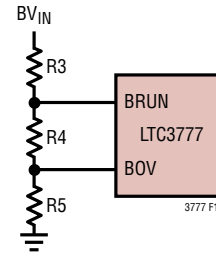
To minimize the no-load supply current, resistor values in the megohm range may be used; however, large resistor values should be used with caution. The feedback divider is the only load current when in shutdown. If PCB leakage current to the output node or switch node exceeds the load current, the output voltage will be pulled up. In normal operation, this is generally a minor concern since the load current is much greater than the leakage.

The switching bias supply has a low power shutdown mode controlled by the BRUN pin. Pulling the BRUN pin below 0.7V puts the switching bias supply into a low quiescent current shutdown mode ( $I_Q \sim 1.4\mu A$ ). When the BRUN pin is greater than 1.21V, switching is enabled. Figure 16 shows examples of configurations for driving the BRUN pin from logic.

The BRUN and BOV pins can alternatively be configured as precise undervoltage (UVLO) and overvoltage (OVLO) lockouts on the  $BV_{IN}$  supply with a resistive divider from  $BV_{IN}$  to ground. A simple resistive divider can be used as shown in Figure 17 to meet specific  $BV_{IN}$  voltage requirements.



**Figure 16. BRUN Pin Interface to Logic**



**Figure 17. Switching Bias Supply Adjustable UV and OV Lockout**

The current that flows through the R3-R4-R5 divider will directly add to the shutdown, sleep, and active current of the switching bias supply, and care should be taken to minimize the impact of this current on the overall efficiency of the application circuit. Resistor values in the megohm range may be required to keep the impact on quiescent shutdown and sleep currents low. To pick resistor values, the sum total of  $R3 + R4 + R5$  ( $R_{TOTAL}$ ) should be chosen first based on the allowable DC current that can be drawn from  $BV_{IN}$ . The individual values of R3, R4 and R5 can then be calculated from the following equations:

$$R5 = R_{TOTAL} \cdot \frac{1.21V}{\text{Rising } BV_{IN} \text{ OVLO Threshold}}$$

$$R4 = R_{TOTAL} \cdot \frac{1.21V}{\text{Rising } BV_{IN} \text{ UVLO Threshold}} - R5$$

$$R3 = R_{TOTAL} - R5 - R4$$

For applications that do not need a precise external OVLO, the BOV pin should be tied directly to ground. The BRUN pin in this type of application can be used as an external UVLO using the previous equations with  $R5 = 0\Omega$ .

Similarly, for applications that do not require a precise UVLO, the BRUN pin can be tied to  $BV_{IN}$ . In this configuration, the UVLO threshold is limited to the internal  $BV_{IN}$  UVLO thresholds as shown in the [Electrical Characteristics](#) table. The resistor values for the BOV can be computed using the previous equations with  $R3 = 0\Omega$ .

## APPLICATIONS INFORMATION

Be aware that the BOV pin cannot be allowed to exceed its absolute maximum rating of 6V. To keep the voltage on the BOV pin from exceeding 6V, the following relation should be satisfied:

$$BV_{IN(MAX)} \cdot \left( \frac{R5}{R3+R4+R5} \right) < 6V$$

### Pre-Biased Output Start-Up

There may be situations that require the power supply to start up with a pre-bias on the output capacitors. In this case, it is desirable to start up without discharging that output pre-bias. The LTC3777 can safely power up into a pre-biased output without discharging it.

If the voltage on the SS pin is lower than  $V_{FB}$ , to prevent pulling current from the output to the input, the LTC3777 forces the part into discontinuous mode of operation irrespective of the status of the MODE pin. If  $V_{FB}$  is  $>1.12V$ , or when the SS voltage crosses  $V_{FB}$  or  $1.32V$ , whichever event happens first, then the MODE pin setting determines the mode of operation.

### Topside MOSFET Driver Supply

In the [Block Diagram](#), the external bootstrap capacitors  $C_A$  and  $C_B$ , connected to the BOOST1 and BOOST2 pins, supply the gate drive voltage for the topside MOSFET switches A and D. When the top switch A turns on, the switch node SW1 rises to  $V_{IN}$  and the BOOST1 pin rises to approximately  $V_{IN} + DRV_{CC}$ . When the bottom switch B turns on, the switch node SW1 is low and the boost capacitor  $C_A$  is charged through  $D_A$  from  $DRV_{CC}$ . When the top switch D turns on, the switch node SW2 rises to  $V_{OUT}$  and the BOOST2 pin rises to approximately  $V_{OUT} + DRV_{CC}$ . When the bottom switch C turns on, switch node SW2 is low and the boost capacitor  $C_B$  is charged through  $D_B$  from  $DRV_{CC}$ . The boost capacitors  $C_A$  and  $C_B$  need to store about 100 times the gate charge required by the top switches A and D. In most applications, a  $0.1\mu F$  to  $0.47\mu F$ , X5R or X7R dielectric capacitor is adequate.

### Fault Conditions: Current Limit and Current Foldback

The maximum inductor current is inherently limited in a current mode controller by the maximum sense voltage. In the boost region, maximum sense voltage and the sense resistance determine the maximum allowed inductor peak current, which is:

$$I_{L(MAX,BOOST)} = \frac{140mV}{R_{SENSE}}$$

In the buck region, maximum sense voltage and the sense resistance determine the maximum allowed inductor valley current, which is:

$$I_{L(MAX,BUCK)} = \frac{90mV}{R_{SENSE}}$$

To further limit current in the event of a short circuit to ground, the LTC3777 includes foldback current limiting. If the output falls by more than 50%, then the maximum sense voltage is progressively lowered to about one-third of its full value.

### Efficiency Considerations

The percent efficiency of a switching regulator is equal to the output power divided by the input power times 100%. It is often useful to analyze individual losses to determine what is limiting the efficiency and which change would produce the most improvement. Percent efficiency can be expressed as:

$$\% \text{ Efficiency} = 100\% - (L1 + L2 + L3 + \dots)$$

where L1, L2, etc. are the individual losses as a percentage of input power.

Although all dissipative elements in the circuit produce losses, four main sources usually account for most of the losses in LTC3777 circuits: 1) IC  $V_{IN}$  current, 2) MOSFET driver current, 3)  $I^2R$  losses, 4) topside MOSFET transition losses.

## APPLICATIONS INFORMATION

1. The  $V_{IN}$  current is the DC supply current given in the [Electrical Characteristics](#) table.  $V_{IN}$  current typically results in a small (<0.1%) loss.
2. The MOSFET driver current results from switching the gate capacitance of the power MOSFETs. Each time a MOSFET gate is switched from low to high to low again, a packet of charge  $dQ$  moves from the driver supply to ground. The resulting  $dQ/dt$  is a current out of the driver supply that is typically much larger than the control circuit current. In continuous mode,  $I_{GATECHG} = f(Q_T + Q_B)$ , where  $Q_T$  and  $Q_B$  are the gate charges of the topside and bottom side MOSFETs.
3.  $I^2R$  losses are predicted from the DC resistances of the fuse (if used), MOSFET, inductor and current sense resistor. In continuous mode, the average output current flows through  $L$  and  $R_{SENSE}$ , but is chopped between the topside MOSFET and the synchronous MOSFET. If the two MOSFETs have approximately the same  $R_{DS(ON)}$ , then the resistance of one MOSFET can simply be summed with the resistances of  $L$  and  $R_{SENSE}$  to obtain  $I^2R$  losses. For example, if each  $R_{DS(ON)} = 10m\Omega$ ,  $R_L = 10m\Omega$ ,  $R_{SENSE} = 5m\Omega$ , then the total resistance is  $25m\Omega$ . This results in losses ranging from 0.6% to 2% as the output current increases from 3A to 15A for a 12V output.

Efficiency varies as the inverse square of  $V_{OUT}$  for the same external components and output power level. The combined effects of increasingly lower output voltages and higher currents required by high performance digital systems is not doubling but quadrupling the importance of loss terms in the switching regulator system!

4. Transition losses apply only to the topside MOSFET(s), and become significant only when operating at high input voltages (typically 15V or greater). Transition losses can be estimated from:

$$\text{Transition Loss} = (1.7) V_{IN}^2 \cdot I_{O(MAX)} \cdot C_{RSS} \cdot f$$

Other hidden losses such as copper trace and internal battery resistances can account for an additional 5%

to 10% efficiency degradation in portable systems. It is very important to include these system level losses during the design phase. The internal battery and fuse resistance losses can be minimized by making sure that  $C_{IN}$  has adequate charge storage and very low ESR at the switching frequency. A 25W supply will typically require a minimum of  $20\mu F$  to  $40\mu F$  of capacitance having a maximum of  $20m\Omega$  to  $50m\Omega$  of ESR. Other losses including Schottky conduction losses during dead time and inductor core losses generally account for less than 2% total additional loss.

### Checking Transient Response

The regulator loop response can be checked by looking at the load current transient response. Switching regulators take several cycles to respond to a step in DC (resistive) load current. When a load step occurs,  $V_{OUT}$  shifts by an amount equal to  $\Delta I_{LOAD} \cdot ESR$ , where ESR is the effective series resistance of  $C_{OUT}$ .  $\Delta I_{LOAD}$  also begins to charge or discharge  $C_{OUT}$  generating the feedback error signal that forces the regulator to adapt to the current change and return  $V_{OUT}$  to its steady-state value. During this recovery time  $V_{OUT}$  can be monitored for excessive overshoot or ringing, which would indicate a stability problem. The availability of the ITH pin not only allows optimization of control loop behavior but also provides a DC-coupled and AC-filtered closed-loop response test point. The DC step, rise time and settling at this test point truly reflects the closed-loop response. Assuming a predominantly second order system, phase margin and/or damping factor can be estimated using the percentage of overshoot seen at this pin. The bandwidth can also be estimated by examining the rise time at the pin.

The ITH external components shown in the Typical Application circuit will provide an adequate starting point for most applications. The ITH series  $R_C$ - $C_C$  filter sets the dominant pole-zero loop compensation. The values can be modified slightly (from 0.5 to 2 times their suggested values) to optimize transient response once the final PC layout is done and the particular output capacitor type and value have been determined. The output capacitors



## APPLICATIONS INFORMATION

need to be selected because the various types and values determine the loop gain and phase. An output current pulse of 20% to 80% of full-load current having a rise time of 1 $\mu$ s to 10 $\mu$ s will produce output voltage and ITH pin waveforms that will give a sense of the overall loop stability without breaking the feedback loop.

Placing a power MOSFET directly across the output capacitor and driving the gate with an appropriate signal generator is a practical way to produce a realistic load step condition. The initial output voltage step resulting from the step change in output current may not be within the bandwidth of the feedback loop, so this signal cannot be used to determine phase margin. This is why it is better to look at the ITH pin signal which is in the feedback loop and is the filtered and compensated control loop response.

The gain of the loop will be increased by increasing  $R_C$  and the bandwidth of the loop will be increased by decreasing  $C_C$ . If  $R_C$  is increased by the same factor that  $C_C$  is decreased, the zero frequency will be kept the same, thereby keeping the phase shift the same in the most critical frequency range of the feedback loop. The output voltage settling behavior is related to the stability of the closed-loop system and will demonstrate the actual overall supply performance.

A second, more severe transient is caused by switching in loads with large (>1 $\mu$ F) supply bypass capacitors. The discharged bypass capacitors are effectively put in parallel with  $C_{OUT}$ , causing a rapid drop in  $V_{OUT}$ . No regulator can alter its delivery of current quickly enough to prevent this sudden step change in output voltage if the load switch resistance is low and it is driven quickly. If the ratio of  $C_{LOAD}$  to  $C_{OUT}$  is greater than 1:50, the switch rise time should be controlled so that the load rise time is limited to approximately  $25 \cdot C_{LOAD}$ . Thus a 10 $\mu$ F capacitor would require a 250 $\mu$ s rise time, limiting the charging current to about 200mA.

### PC Board Layout Checklist

When laying out the printed circuit board, the following checklist should be used to ensure proper operation of the IC.

1. Are the signal and power grounds kept separate? The combined IC signal ground pin and the ground return of  $C_{DRVCC}$  must return to the combined  $C_{OUT}$  (-) terminals. The path formed by the top N-channel MOSFET, bottom N-channel MOSFET and the  $C_{IN}$  capacitor should have short leads and PC trace lengths. The output capacitor (-) terminals should be connected as close as possible to the (-) terminals of the input capacitor by placing the capacitors next to each other.
2. Does the LTC3777  $V_{FB}$  pin's resistive divider connect to the (+) terminal of  $C_{OUT}$ ? The resistive divider must be connected between the (+) terminal of  $C_{OUT}$  and signal ground. The feedback resistor connections should not be along the high current input feeds from the input capacitor(s).
3. Are the SENSEN and SENSEP leads routed together with minimum PC trace spacing? The filter capacitor between SENSE+ and SENSE- should be as close as possible to the IC. Ensure accurate current sensing with Kelvin connections at the SENSE resistor.
4. Is the  $DRV_{CC}$  and decoupling capacitor connected close to the IC, between the  $DRV_{CC}$  and the ground pin? This capacitor carries the MOSFET drivers' current peaks.
5. Keep the SW, TG, and BOOST nodes away from sensitive small-signal nodes. All of these nodes have very large and fast moving signals and therefore should be kept on the output side of the LTC3777 and occupy minimum PC trace area.
6. The path formed by switch A, switch B, D1 and the  $C_{IN}$  capacitor should have short leads and PC trace lengths. The path formed by switch C, switch D, D2 and the  $C_{OUT}$  capacitor also should have short leads and PC trace lengths.

## APPLICATIONS INFORMATION

7. Use a modified star ground technique: a low impedance, large copper area central grounding point on the same side of the PC board as the input and output capacitors with tie-ins for the bottom of the DRV<sub>CC</sub> decoupling capacitor, the bottom of the voltage feedback resistive divider and the GND pin of the IC.

### Design Example

$$V_{IN} = 6V \text{ to } 100V$$

$$V_{OUT} = 12V$$

$$I_{OUT(MAX)} = 5A$$

$$f = 200kHz$$

$$\text{Maximum ambient temperature} = 60^{\circ}C$$

Set the frequency at 200kHz by applying 1.11V on the FREQ pin (see Figure 9). The 20 $\mu$ A current flowing out of the FREQ pin will give 1.11V across a 55.6k resistor to GND. The inductance value is chosen first based on a 30% ripple current assumption. In the buck region, the ripple current is:

$$\Delta I_{L,BUCK} = \frac{V_{OUT}}{f \cdot L} \cdot \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

$$I_{RIPPLE,BUCK} = \frac{\Delta I_{L,BUCK} \cdot 100}{I_{OUT}} \%$$

The highest value of ripple current occurs at the maximum input voltage. In the boost region, the ripple current is:

$$\Delta I_{L,BOOST} = \frac{V_{IN}}{f \cdot L} \cdot \left(1 - \frac{V_{IN}}{V_{OUT}}\right)$$

$$I_{RIPPLE,BOOST} = \frac{\Delta I_{L,BOOST} \cdot 100}{I_{IN}} \%$$

The highest value of ripple current occurs at  $V_{IN} = V_{OUT}/2$ .

A 15 $\mu$ H inductor will produce 10% ripple in the boost region ( $V_{IN} = 6V$ ) and 70% ripple in the buck region ( $V_{IN} = 100V$ ).

The R<sub>SENSE</sub> resistor value can be calculated by using the maximum current sense voltage specification with some accommodation for tolerances.

$$R_{SENSE} = \frac{2 \cdot 140mV \cdot V_{IN(MIN)}}{2 \cdot I_{OUT(MAX,BOOST)} \cdot V_{OUT} + \Delta I_{L,BOOST} \cdot V_{IN(MIN)}} \\ = 13.3m\Omega$$

Adding an additional 30% margin, choose R<sub>SENSE</sub> to be 13.3m $\Omega$ /1.3 = 10m $\Omega$ .

Output voltage is 12V. Select R<sub>A</sub> as 12.1k. R<sub>B</sub> is:

$$R_B = \frac{V_{OUT} \cdot R_A}{1.2} - R_A$$

Select R<sub>B</sub> as 110k. Both R<sub>A</sub> and R<sub>B</sub> should have a tolerance of no more than 1%.

### Selecting MOSFET Switches

The MOSFETs are selected based on voltage rating and R<sub>DS(ON)</sub> value. It is important to ensure that the part is specified for operation with the available gate voltage amplitude. In this case, the amplitude is 10V and MOSFETs with an R<sub>DS(ON)</sub> value specified at V<sub>GS</sub> = 4.5V can be used.

*Select QA and QB.* With 100V maximum input voltage MOSFETs with a rating of at least 150V are used. As we do not yet know the actual thermal resistance (circuit board design and airflow have a major impact) we assume that the MOSFET thermal resistance from junction to ambient is 50 $^{\circ}C/W$ .

If we design for a maximum junction temperature, T<sub>J(MAX)</sub> = 125 $^{\circ}C$ , the maximum R<sub>DS(ON)</sub> value can be calculated. First, calculate the maximum power dissipation:

$$P_{D(MAX)} = \left( \frac{T_{J(MAX)} - T_{A(MAX)}}{R_{(j-a)}} \right)$$

$$P_{D(MAX)} = \frac{(125 - 60)}{50} = 1.3W$$

## APPLICATIONS INFORMATION

The maximum dissipation in QA occurs at minimum input voltage when the circuit operates in the boost region and QA is on continuously. The input current is then:

$$\frac{V_{OUT} \cdot I_{OUT(MAX)}}{V_{IN(MIN)}}, \text{ or } 10A$$

We calculate a maximum value for  $R_{DS(ON)}$ :

$$R_{DS(ON)}(125^{\circ}C) < \frac{P_{D(MAX)}}{I_{IN(MAX)}^2}$$

$$R_{DS(ON)}(125^{\circ}C) < \frac{1.3W}{(10A)^2} = 0.013\Omega$$

The Infineon BSC360N15NS3G has a typical  $R_{DS(ON)}$  of  $0.036\Omega$  at  $V_{GS} = 10V$ . Two MOSFETs can be used in parallel to handle the power dissipation.

The maximum dissipation in QB occurs at maximum input voltage when the circuit is operating in the buck region. The dissipation is:

$$P_{B,BUCK} = \frac{V_{IN} - V_{OUT}}{V_{IN}} \cdot I_{OUT(MAX)}^2 \cdot \rho_{\tau} \cdot R_{DS(ON)}$$

$$R_{DS(ON)}(125^{\circ}C) < \frac{1.3W}{\left(\frac{100V - 12V}{100V}\right) \cdot (5A)^2} = 0.059\Omega$$

The Infineon BSC190N15NS3G with a typical  $R_{DS(ON)}$  of  $19m\Omega$  can be used.

*Select QC and QD.* With 12V output voltage we need MOSFETs with 20V or higher rating.

The highest dissipation occurs at minimum input voltage when the inductor current is highest. For switch QC the dissipation is:

$$P_{C,BOOST} = \frac{(V_{OUT} - V_{IN})V_{OUT}}{V_{IN}^2} \cdot I_{OUT(MAX)}^2 \cdot \rho_{\tau} \cdot R_{DS(ON)} + k \cdot V_{OUT}^3 \cdot \frac{I_{OUT(MAX)}}{V_{IN}} \cdot C_{RSS} \cdot f$$

where  $C_{RSS}$  is usually specified by the MOSFET manufacturers. The constant  $k$ , which accounts for the loss caused by reverse recovery current, is inversely proportional to the gate drive current and has an empirical value of 1.7.

The dissipation in switch QD is:

$$P_{D,BOOST} = \frac{V_{IN}}{V_{OUT}} \cdot \left( \frac{V_{OUT}}{V_{IN}} \cdot I_{OUT(MAX)} \right)^2 \cdot \rho_{\tau} \cdot R_{DS(ON)}$$

BSC050NE2LS is a possible choice for QC and QD. The calculated power loss at 6V input voltage is then 0.392W for QC and 0.375W for QD.

$C_{IN}$  is chosen to filter the square current in the buck region. In this mode, the maximum input current peak is:

$$I_{IN,PEAK(MAX,BUCK)} = 5A \cdot \left( 1 + \frac{70\%}{2 \cdot 100\%} \right) = 6.75A$$

A low ESR ( $10m\Omega$ ) capacitor is selected. Input voltage ripple is 67.5mV (assuming ESR dominates the ripple).

$C_{OUT}$  is chosen to filter the square current in the boost region. In this mode, the maximum output current peak is:

$$I_{OUT,PEAK(MAX,BOOST)} = \frac{12}{6} \cdot 5 \cdot \left( 1 + \frac{10\%}{2 \cdot 100\%} \right) = 10.5A$$

A low ESR ( $5m\Omega$ ) capacitor is suggested. This capacitor will limit output voltage ripple to 53mV (assuming ESR dominates the ripple).

APPLICATIONS INFORMATION

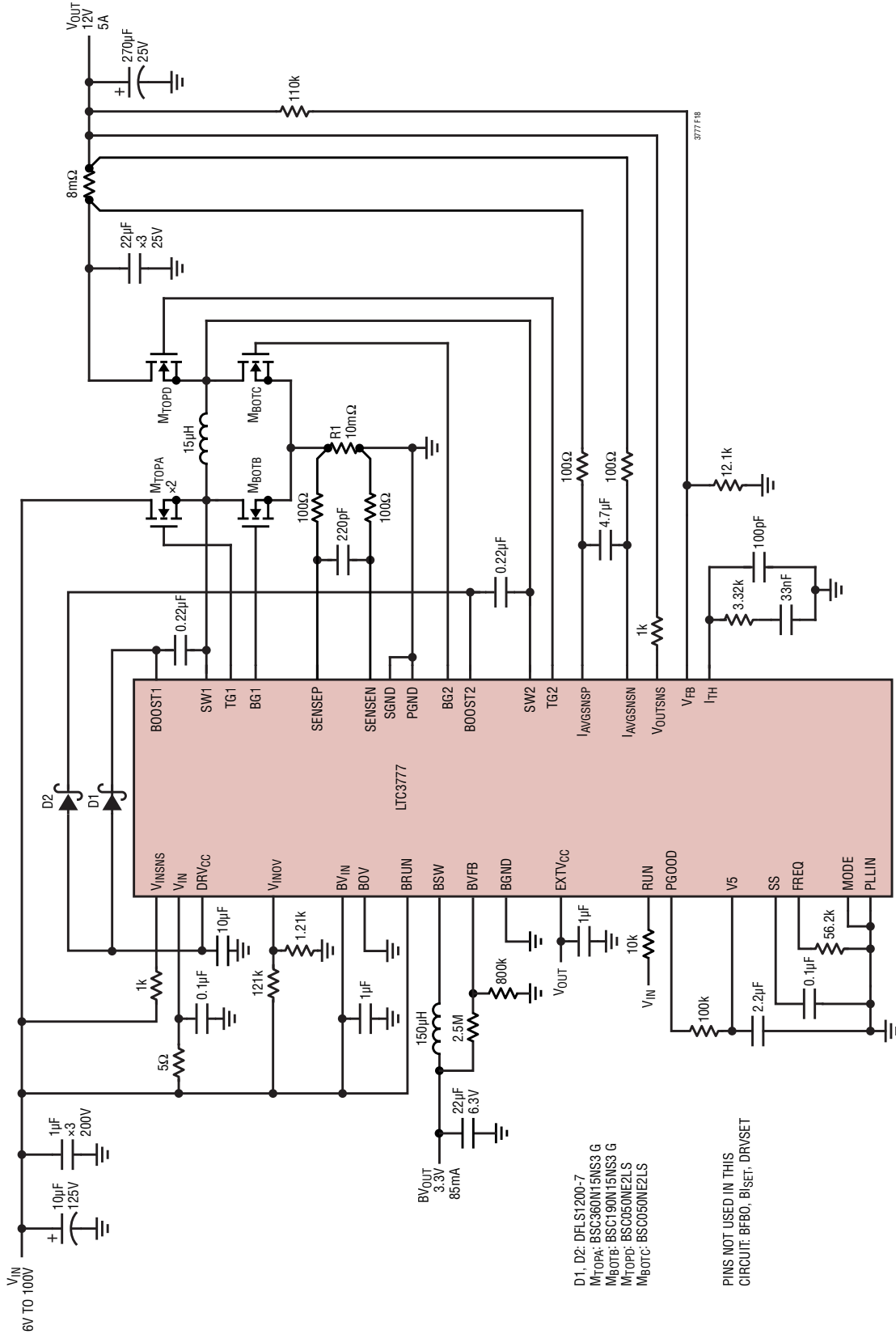
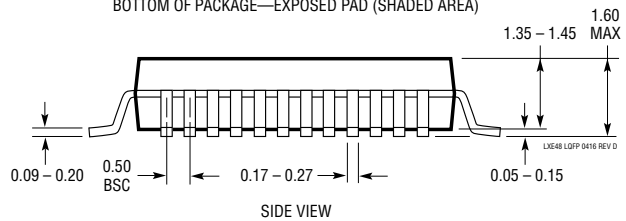
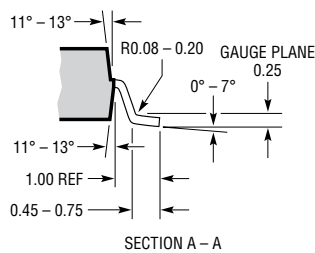
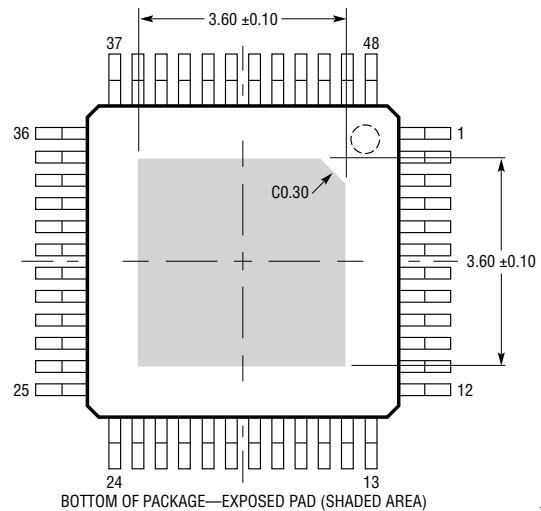
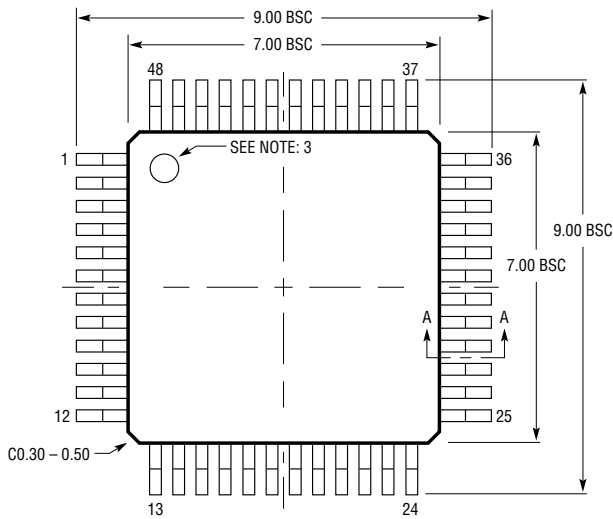
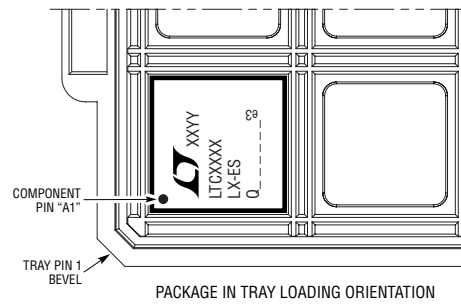
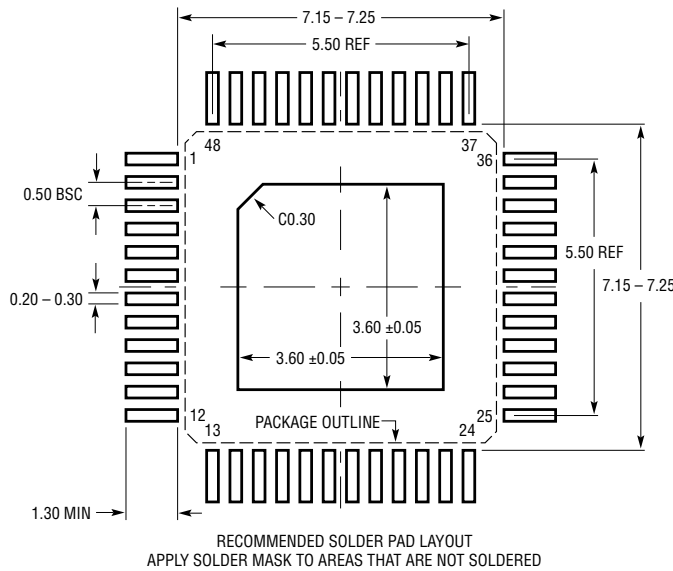


Figure 18. 97% Efficient 12V/5A Output Buck-Boost Converter with an Independent Always on 3.3V/ 85mA Output Switching Bias Supply

# PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LTC3777#packaging> for the most recent package drawings.

## LXE Package 48-Lead Plastic Exposed Pad LQFP (7mm × 7mm) (Reference LTC DWG #05-08-1832 Rev D)



NOTE:

1. DIMENSIONS ARE IN MILLIMETERS
2. DIMENSIONS OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.25mm (10 MILS) BETWEEN THE LEADS AND ON ANY SIDE OF EXPOSED PAD, MAX 0.50mm (20 MILS) AT CORNER OF EXPOSED PAD, IF PRESENT
3. PIN-1 IDENTIFIER IS A MOLDED INDENTATION, 0.50mm DIAMETER
4. DRAWING IS NOT TO SCALE

## TYPICAL APPLICATION

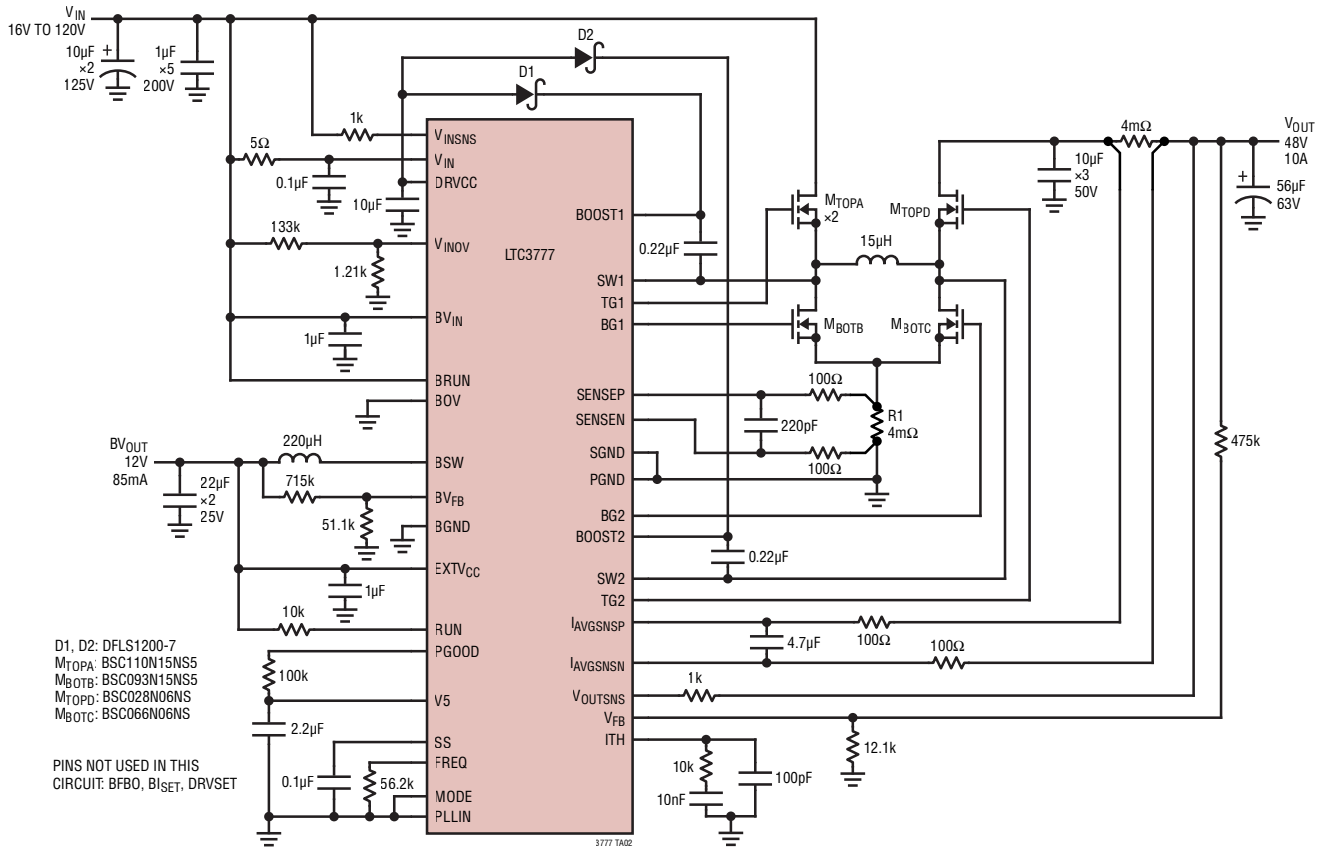


Figure 19. 99% Efficient 480W, 48V Output Buck-Boost Converter with Integrated Switching Bias Supply

## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
<a href="#">LTC3779</a>	150V V <sub>IN</sub> and V <sub>OUT</sub> Synchronous 4-Switch Buck-Boost Controller	4.5V ≤ V <sub>IN</sub> ≤ 150V, 1.2V ≤ V <sub>OUT</sub> ≤ 150V, Up to 99% Efficiency Drives Logic-Level or STD Threshold MOSFETs, TSSOP-38
<a href="#">LT®8705A</a>	80V V <sub>IN</sub> and V <sub>OUT</sub> Synchronous 4-Switch Buck-Boost DC/DC Controller	2.8V ≤ V <sub>IN</sub> ≤ 80V, Input and Output Current Monitor, 5mm × 7mm QFN-38 and TSSOP-38
<a href="#">LTC7813</a>	60V Low I <sub>Q</sub> Synchronous Boost+Buck Controller Low EMI and Low Input/Output Ripple	4.5V (Down to 2.2V After Start-Up) ≤ V <sub>IN</sub> ≤ 60V, Boost V <sub>OUT</sub> Up to 60V, 0.8V ≤ Buck V <sub>OUT</sub> ≤ 60V, I <sub>Q</sub> = 29μA, 5mm × 5mm QFN-32
<a href="#">LTC3899</a>	60V, Triple Output, Buck/Buck/Boost Synchronous Controller with 29μA Burst Mode I <sub>Q</sub>	4.5V (Down to 2.2V After Start-Up) ≤ V <sub>IN</sub> ≤ 60V, V <sub>OUT</sub> Up to 60V, Buck V <sub>OUT</sub> Range: 0.8V to 60V, Boost V <sub>OUT</sub> Up to 60V
<a href="#">LTM®8056</a>	58V Buck-Boost μModule Regulator, Adjustable Input and Output Current Limiting	5V ≤ V <sub>IN</sub> ≤ 58V, 1.2V ≤ V <sub>OUT</sub> ≤ 48V 15mm × 15mm × 4.92mm BGA Package
<a href="#">LTC3895/LTC7801</a>	150V Low I <sub>Q</sub> , Synchronous Step-Down DC/DC Controller with 100% Duty Cycle	4V ≤ V <sub>IN</sub> ≤ 140V, 150V Absolute Maximum, PLL Fixed Frequency 50kHz to 900kHz, 0.8V ≤ V <sub>OUT</sub> ≤ 60V, Adjustable 5V to 10V Gate Drive, I <sub>Q</sub> = 40μA
<a href="#">LTC3871</a>	Bidirectional Multiphase DC/DC Synchronous Buck or Boost On-Demand Controller	V <sub>IN</sub> /V <sub>OUT</sub> Up to 100V, Ideal for High Power 48V/12V Automotive Battery Applications
<a href="#">LTC3638</a>	140V High Efficiency 250mA Step-Down Regulator	Integrated Power MOSFETs, 4V ≤ V <sub>IN</sub> ≤ 140V, 0.8V ≤ V <sub>OUT</sub> ≤ V <sub>IN</sub> , I <sub>Q</sub> = 12μA, MSOP-16(12)
<a href="#">LTC7103</a>	105V, 2.3A Low EMI Synchronous Step-Down Regulator	4.4V ≤ V <sub>IN</sub> ≤ 105V, 1V ≤ V <sub>OUT</sub> ≤ V <sub>IN</sub> , I <sub>Q</sub> = 2μA Fixed Frequency 200kHz to 2MHz, 5mm × 6mm QFN